



Technical Plasma: Theoretical side

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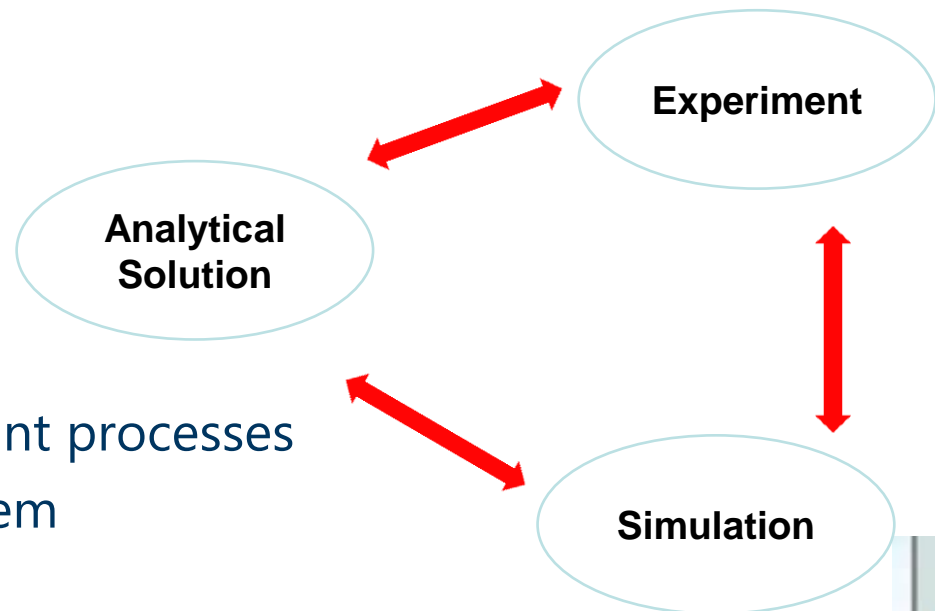
Outline

- **Introduction (some devices and applications)**
- **Challenges of plasma simulation**
- **Kinetic Simulation**
- **Fluid Simulation**
- **Global models and hybrid models**
- **Examples & Conclusion**



Do we need simulation?

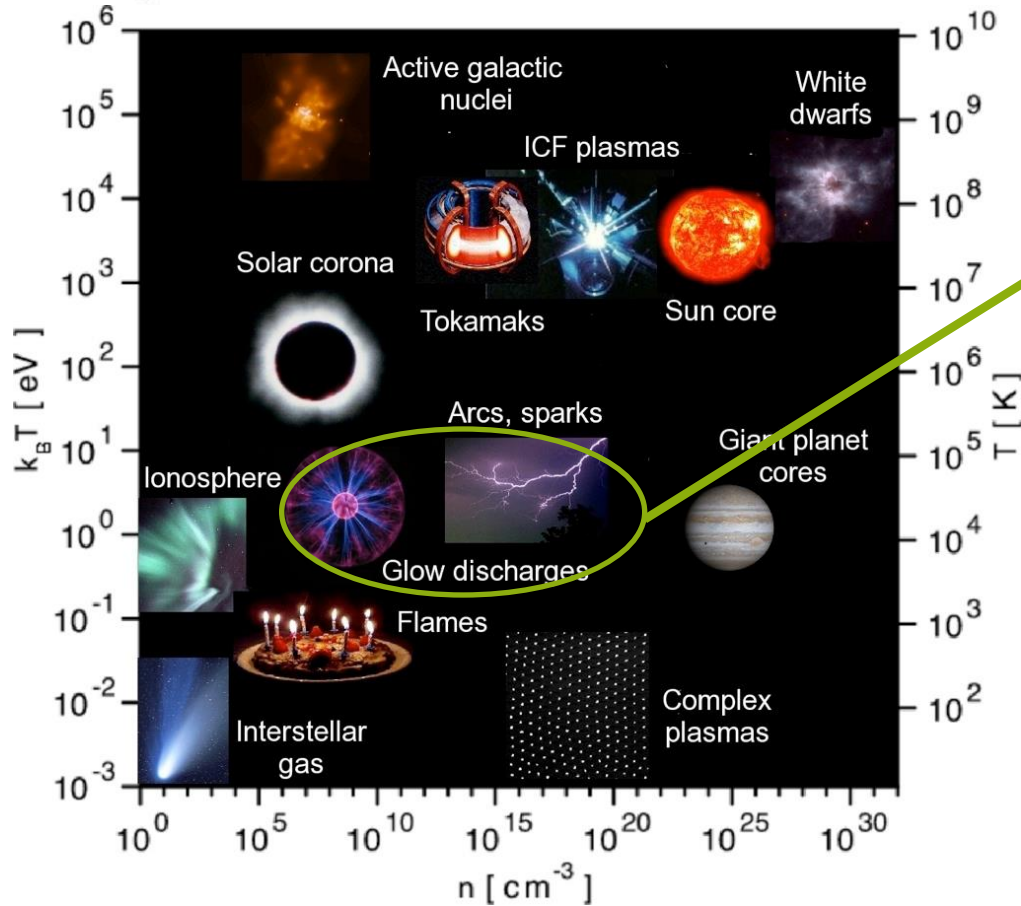
- Simulations are useful
 - For checking theoretical results
 - For cases when no theoretical results are available
 - For understanding experimental observations



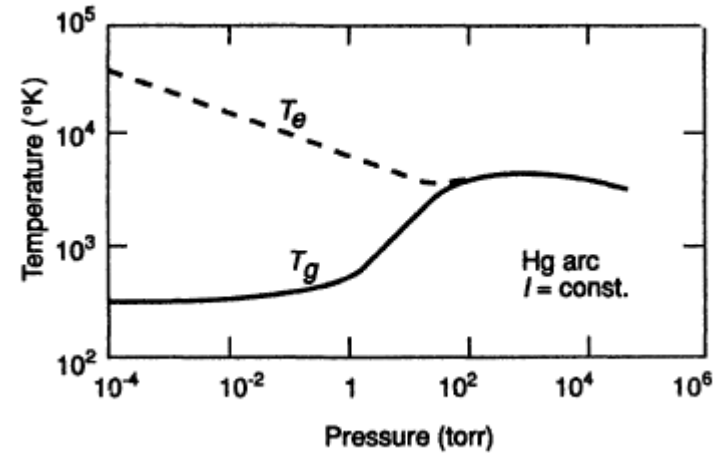
- Simulations allow :
 - Identification of important processes
 - Visualization of the system



Low Temperature Plasma



- Low degree of ionization
- Neutral background 10^6 the ion and electron density
- Collisions with the background gas is dominant compared to electron ion collisions



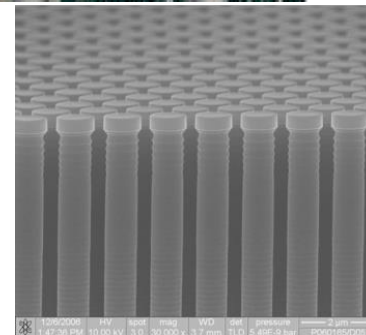
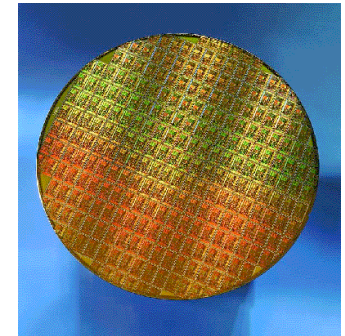
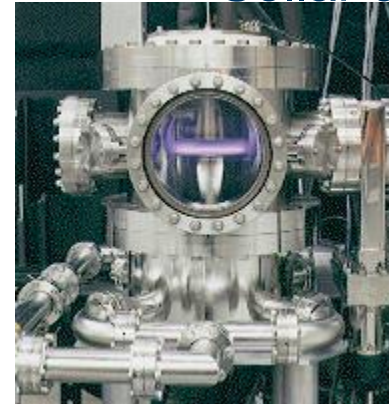
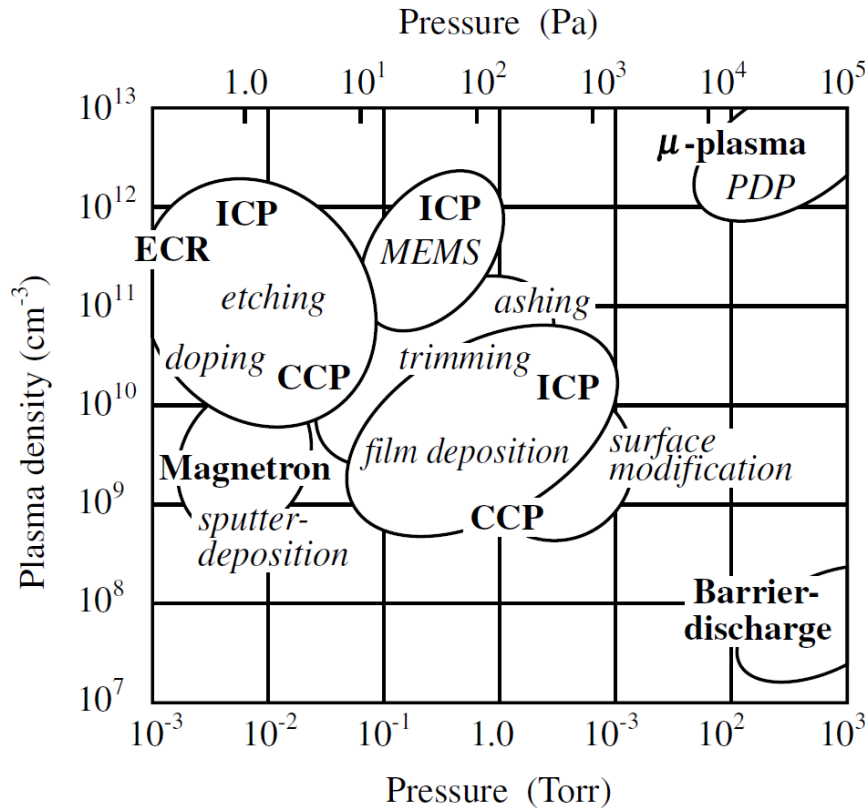
- Non-equilibrium plasmas at low pressures



Devices and applications

- **Capacitive coupled plasma** are used in plasma etching and deposition process for production of:

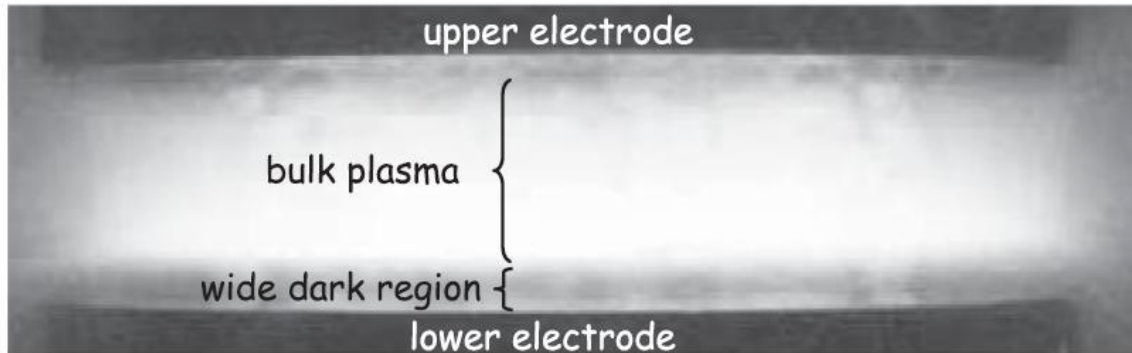
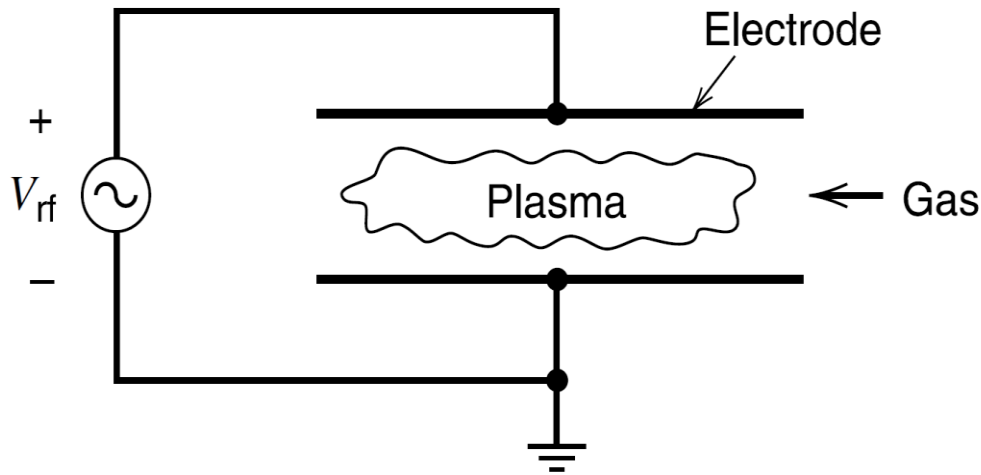
- **Integrated circuits**
- **Sollar cells**



Plasma electronics,
Applications in Microelectronic Device Fabrication



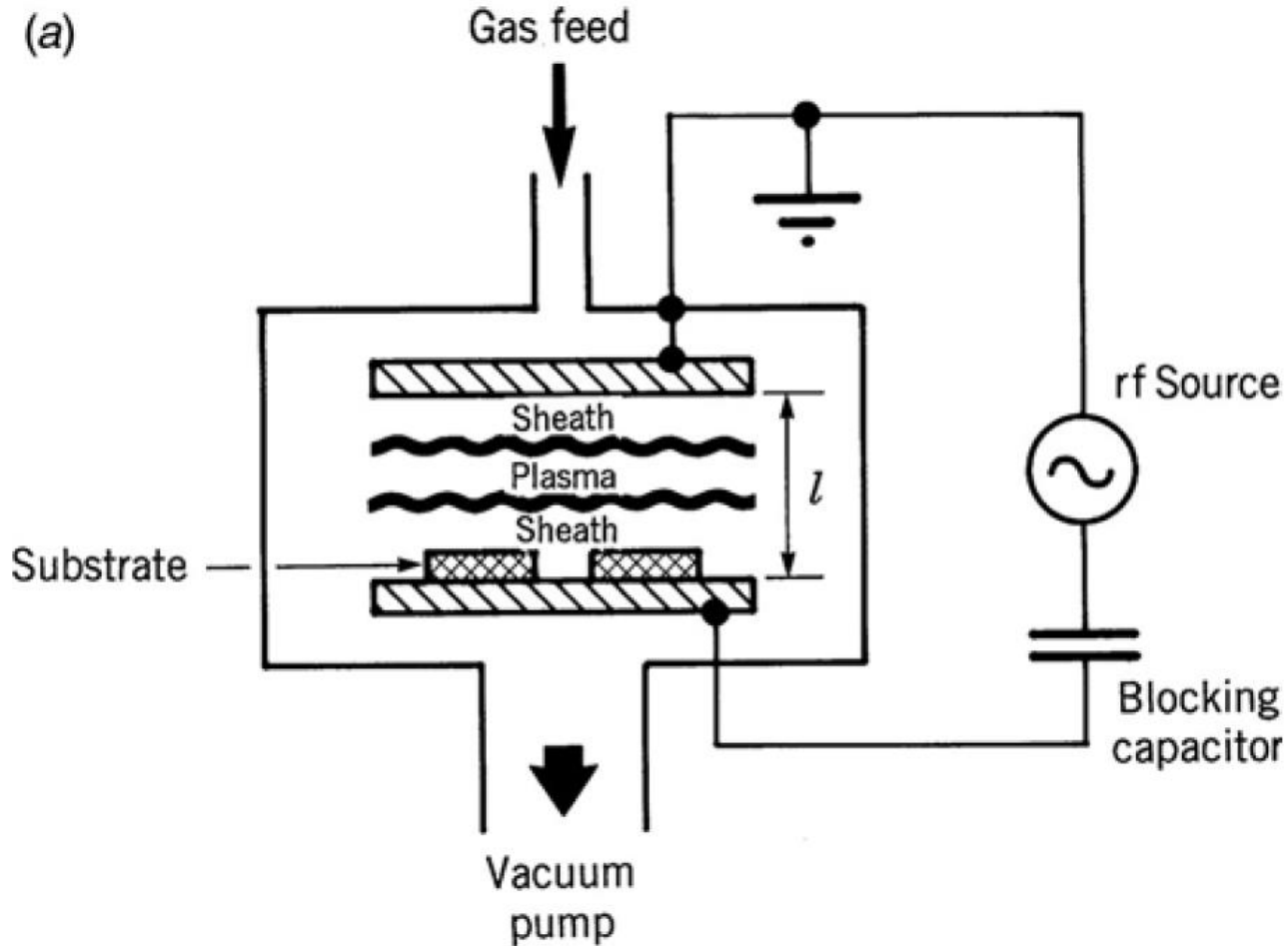
CCP: Symmetric discharge



Kafr Elsheikh University

- The ion flux increases and the ion energies decreases by increasing the driving frequency.!!!!?

CCPs & blocking a Capacitor





Geometrically Asymmetric

- The RF current is constant.
- But the ground electrode Area is greater than the powered electrode area.

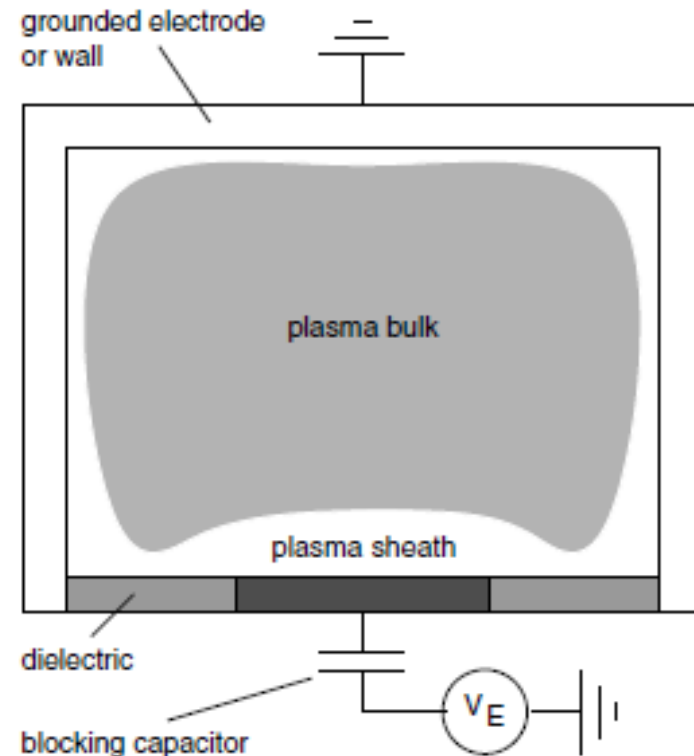
$$J_g = I_{rf} / A_g$$

$$J_p = I_{rf} / A_p$$

$$J_p \gg J_g$$

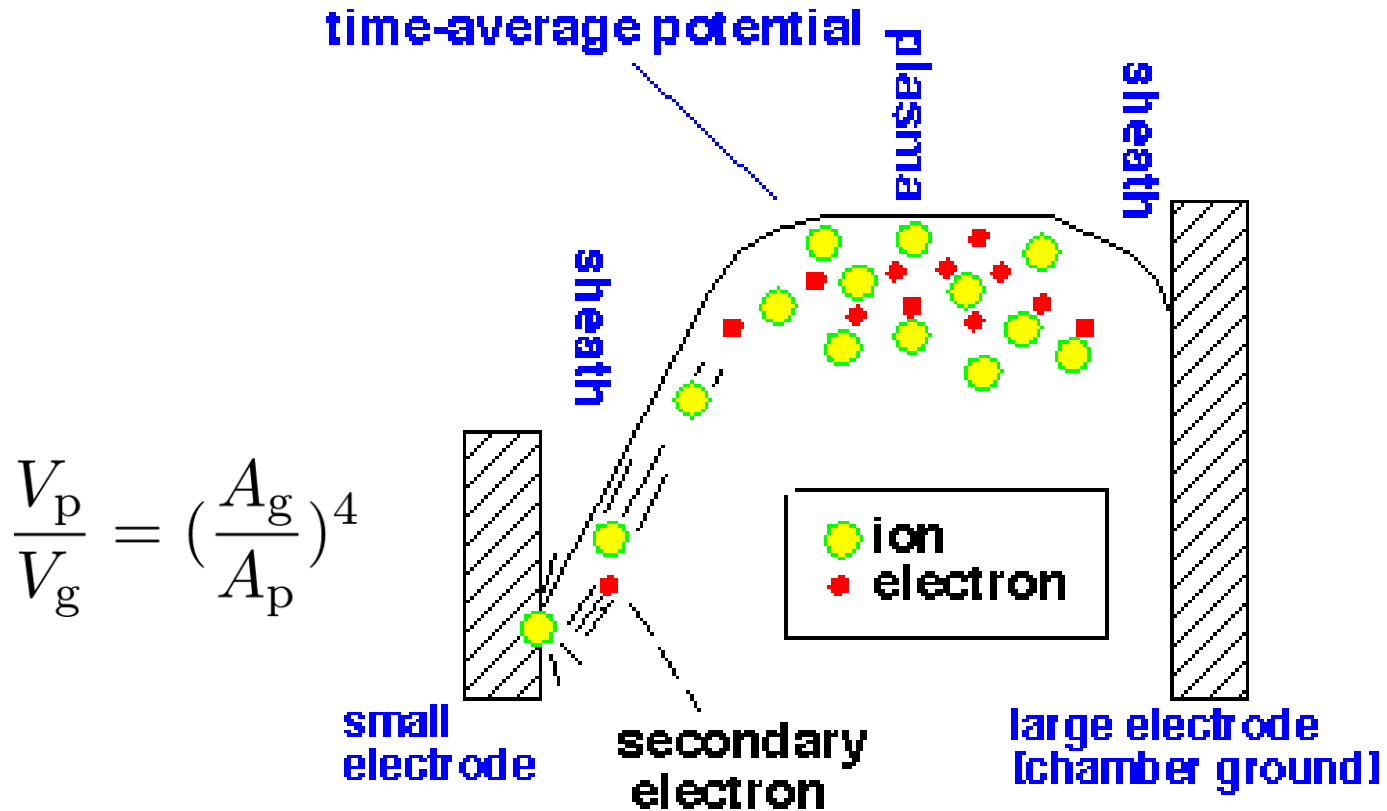
- The blocking capacitor blocks DC currents:

$$\frac{V_p}{V_g} = \left(\frac{A_g}{A_p} \right)^4$$





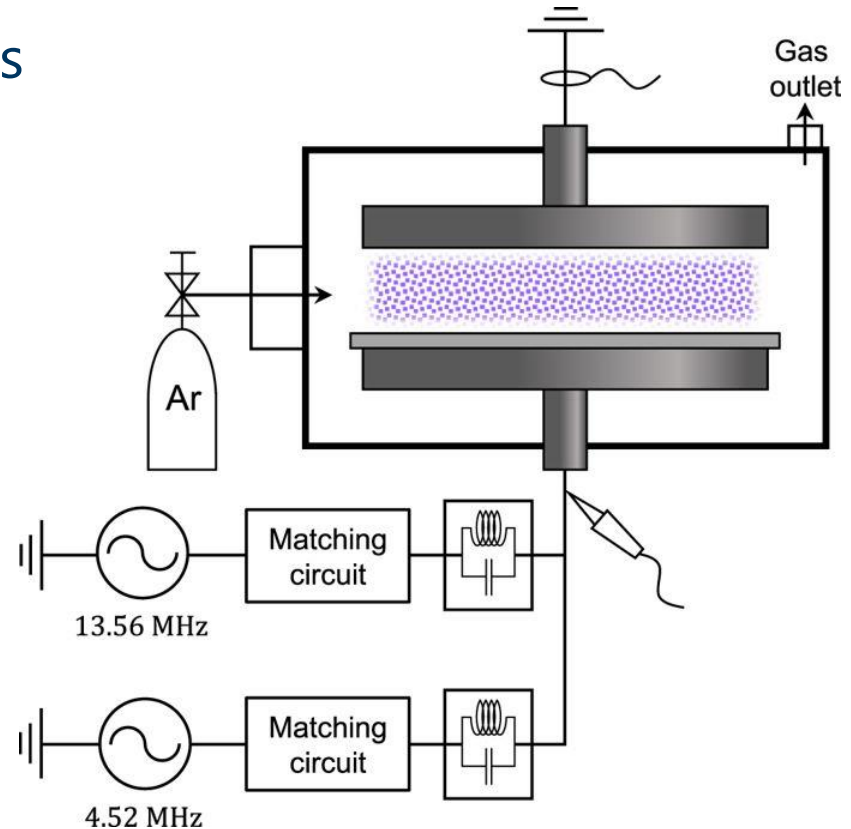
Particle and Potential distribution





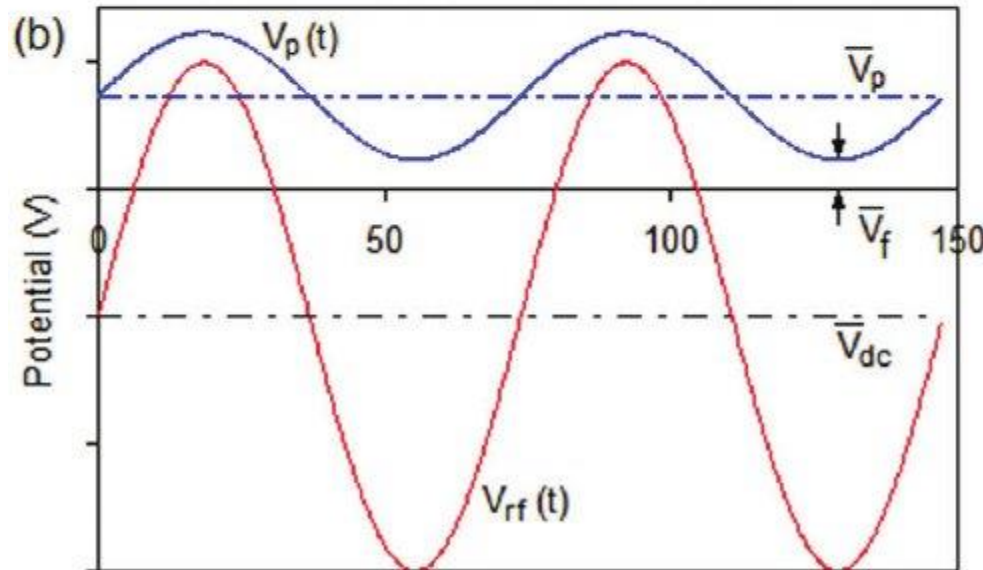
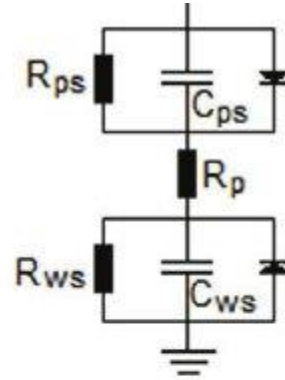
Electrically Asymmetric

- The high frequency controls the ion plasma bulk (ion flux).
- The lower frequency controls the plasma sheath voltage.
- The phase shift between the two sources controls also the sheath potential.
- The independent control is not always perfect.





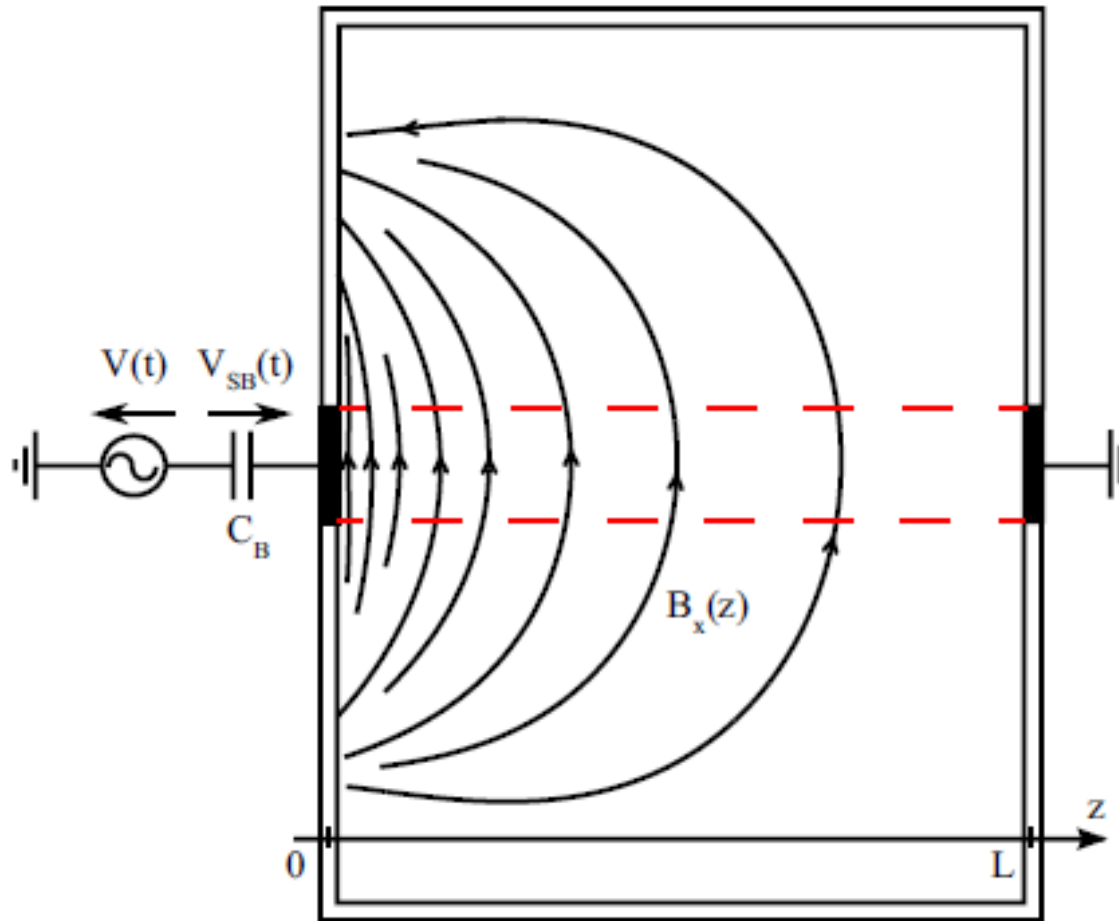
Electrically asymmetric CCP discharges



J. Schulze et al, Ruhr University Bochum

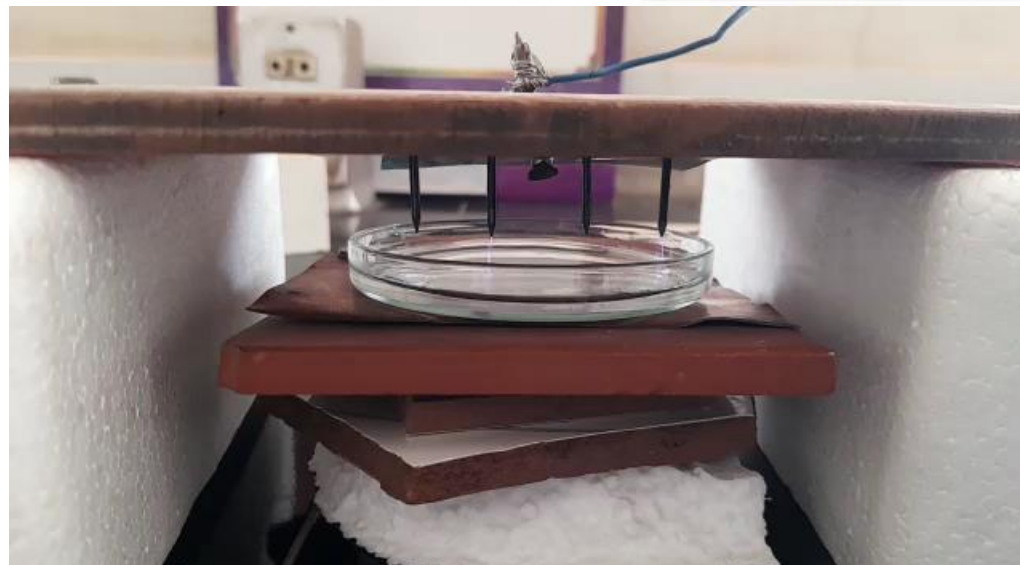
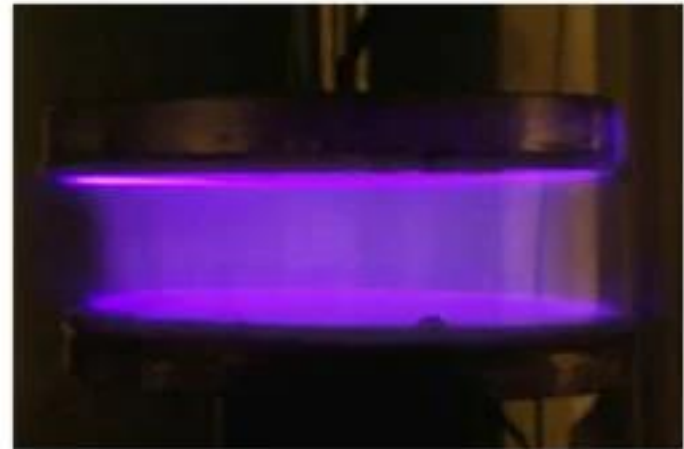
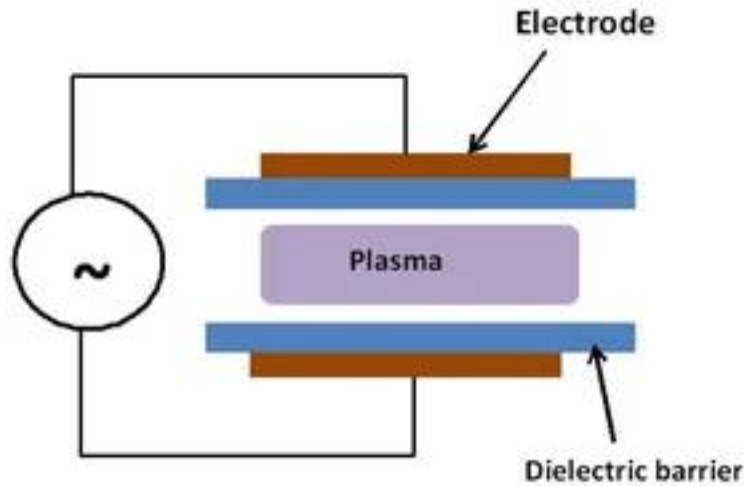


RF Magnetron





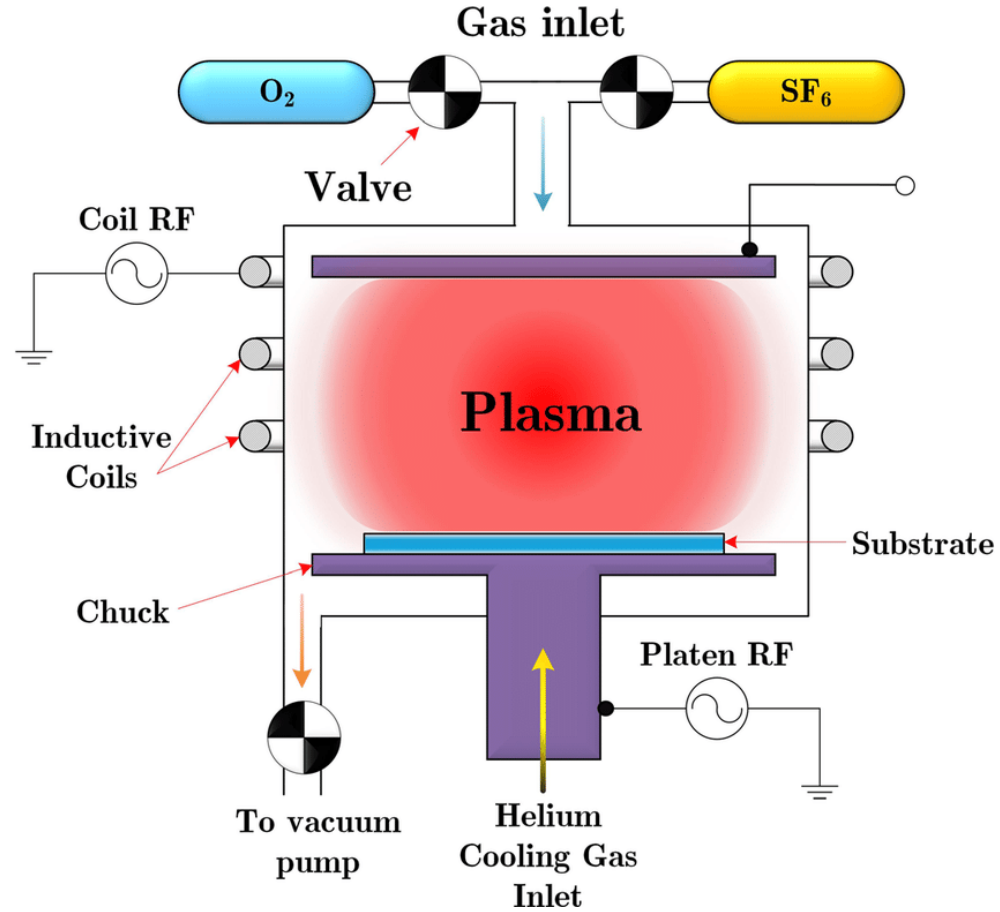
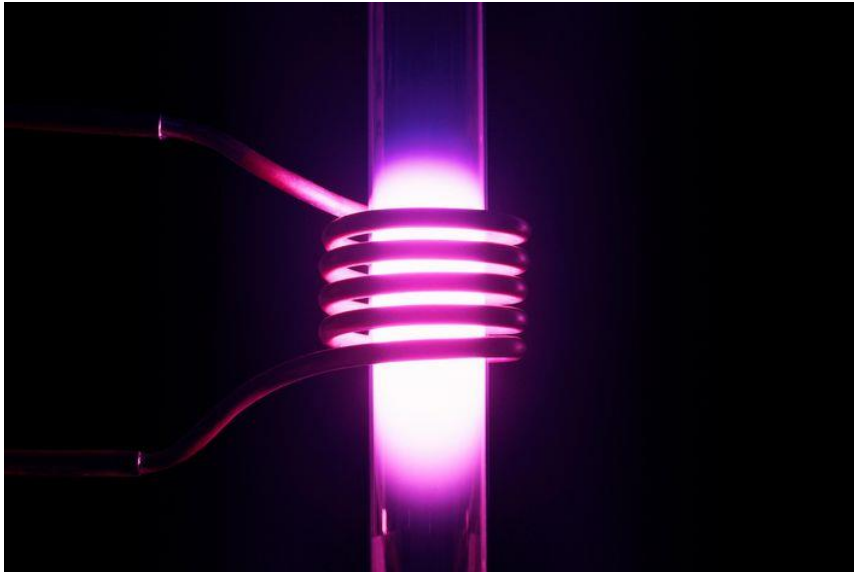
Dielectric barrier discharge



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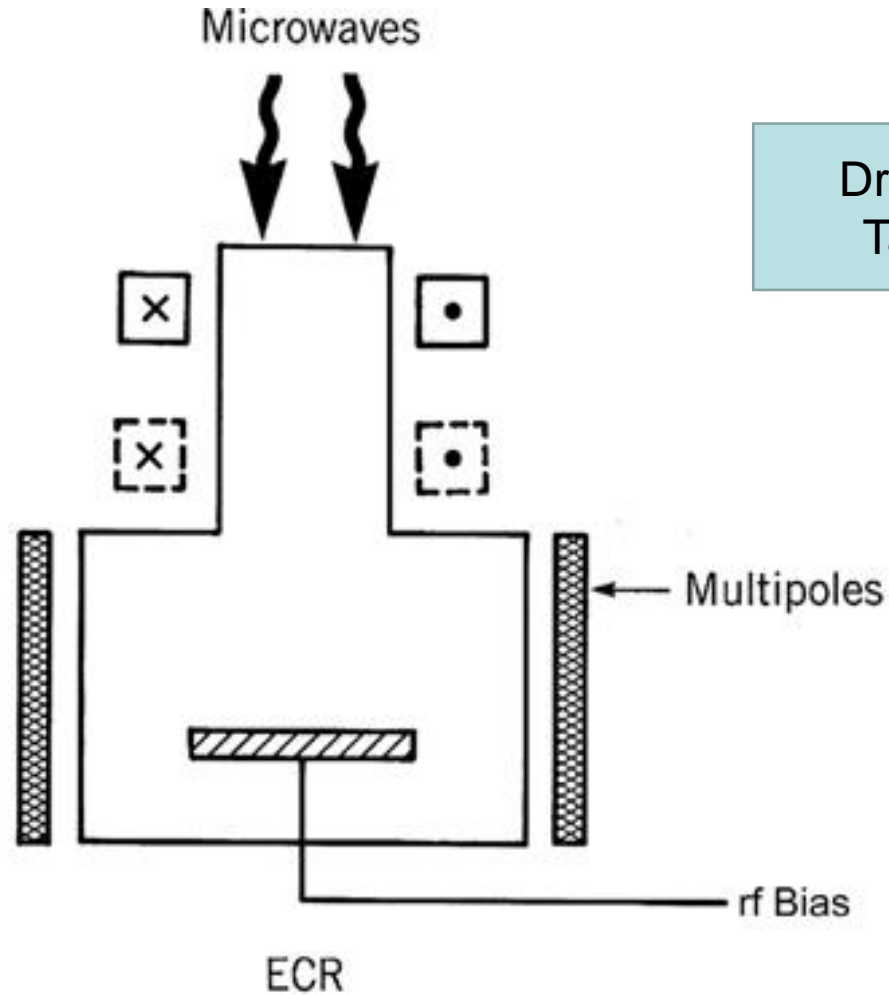


Inductive coupled plasma





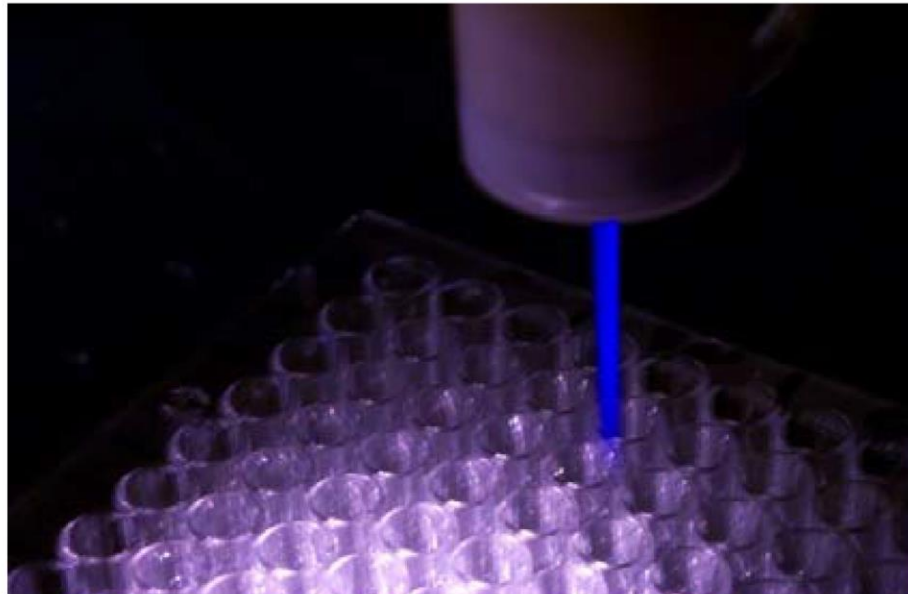
High density sources (ECR)



Dr Shrouk Elashry
Tanta University



Plasma jets



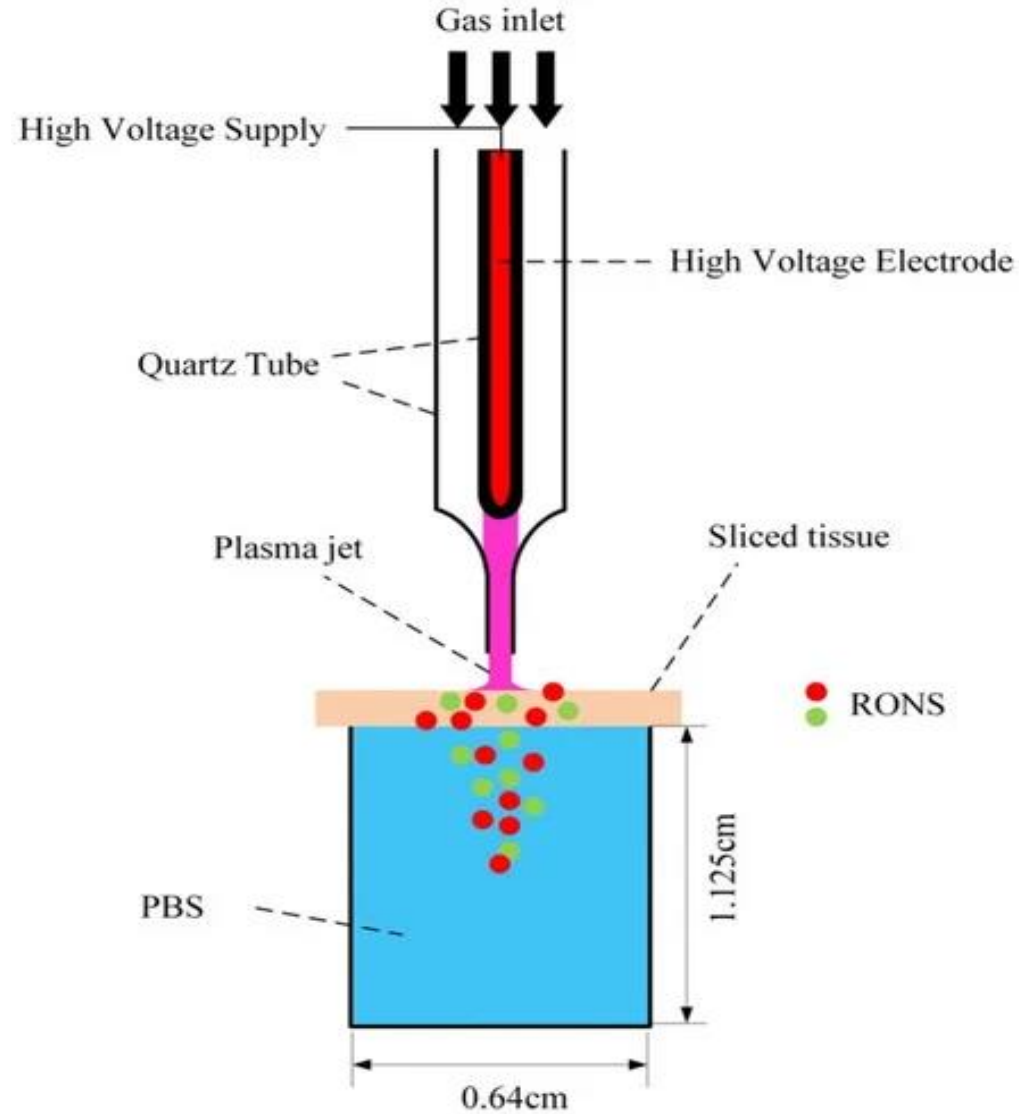
(a)



(b)

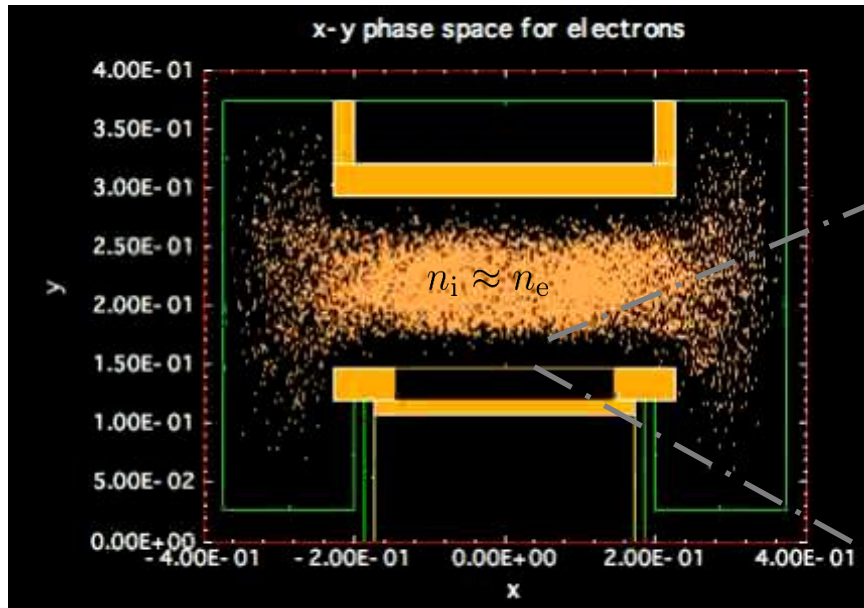


Plasma jets

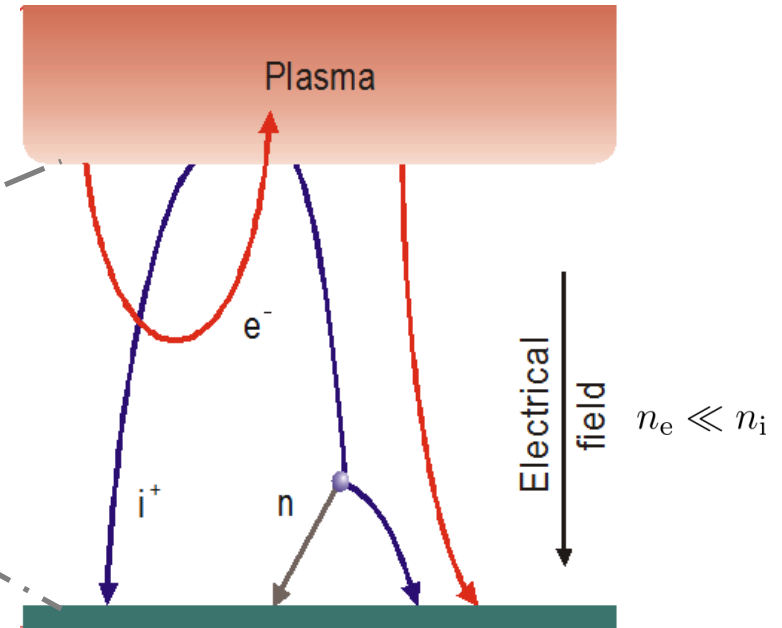




Plasma sheaths



TET



- RF sheaths:
 - High frequency regime
 - Intermediate frequency regime
 - Low frequency regime

$$\omega_{RF} \gg \omega_{pi}$$

$$n_i(x) \Leftrightarrow \bar{E}(x)$$

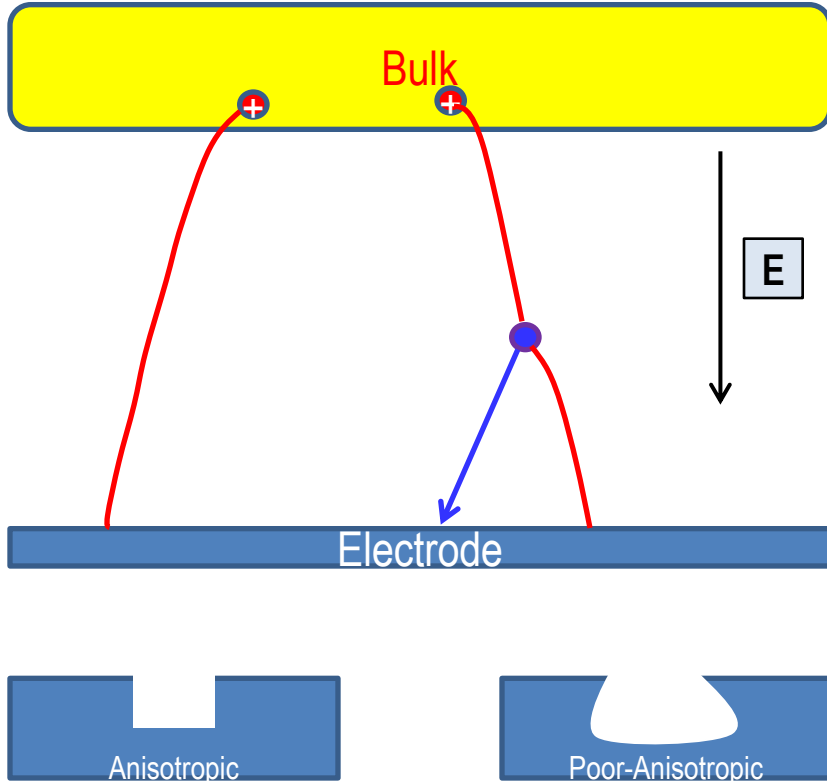
$$\omega_{RF} \approx \omega_{pi}$$

$$\omega_{RF} \ll \omega_{pi}$$

$$n_i(x, t) \Leftrightarrow E(x, t)$$



Plasma Processing



Intel

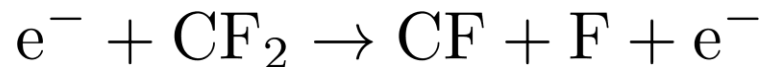


Plasma Chemistry

- **Dissociation of feedstock gas into active neutral free radicals:**

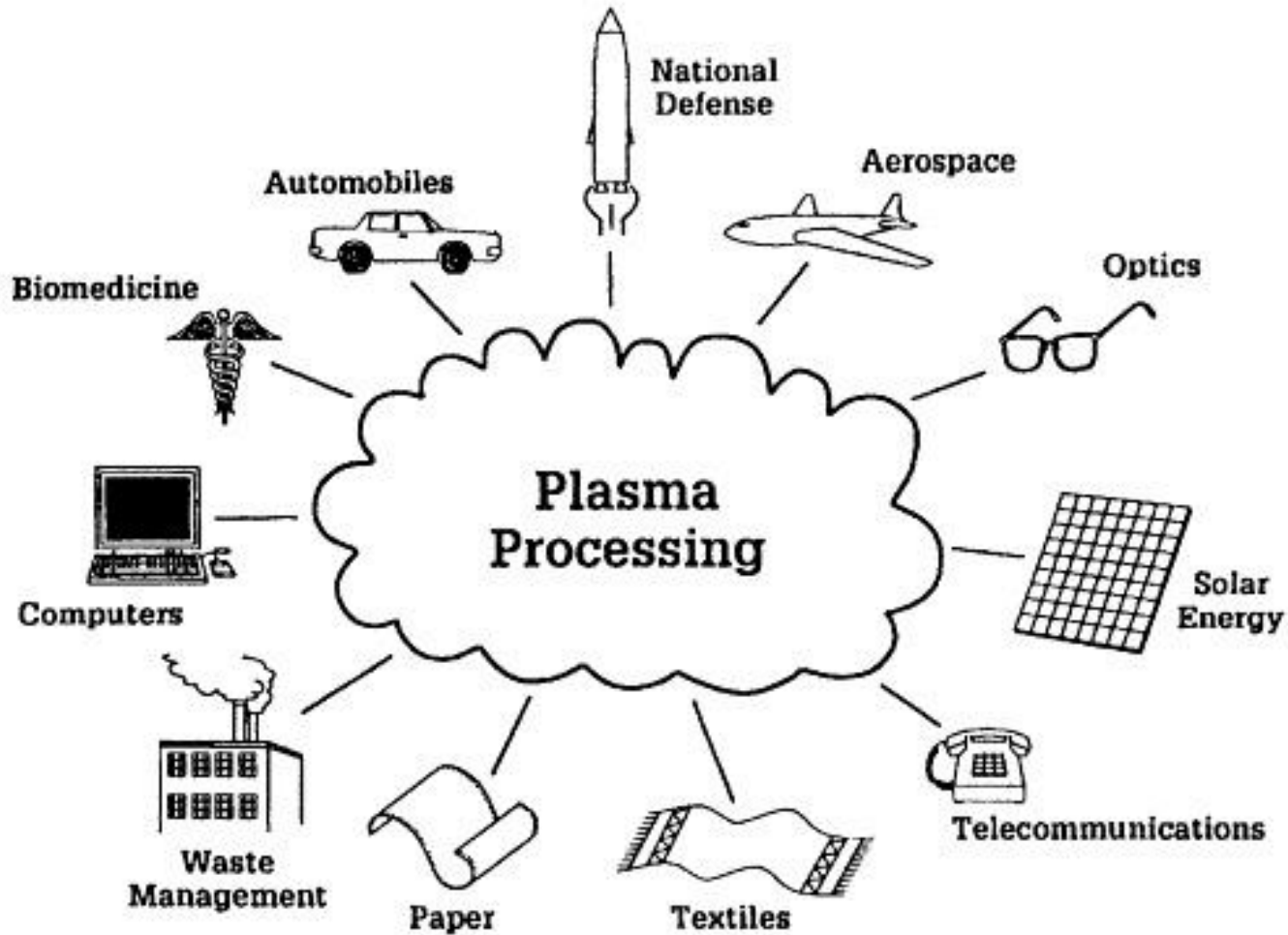


- **Dissociation of the free radicals**



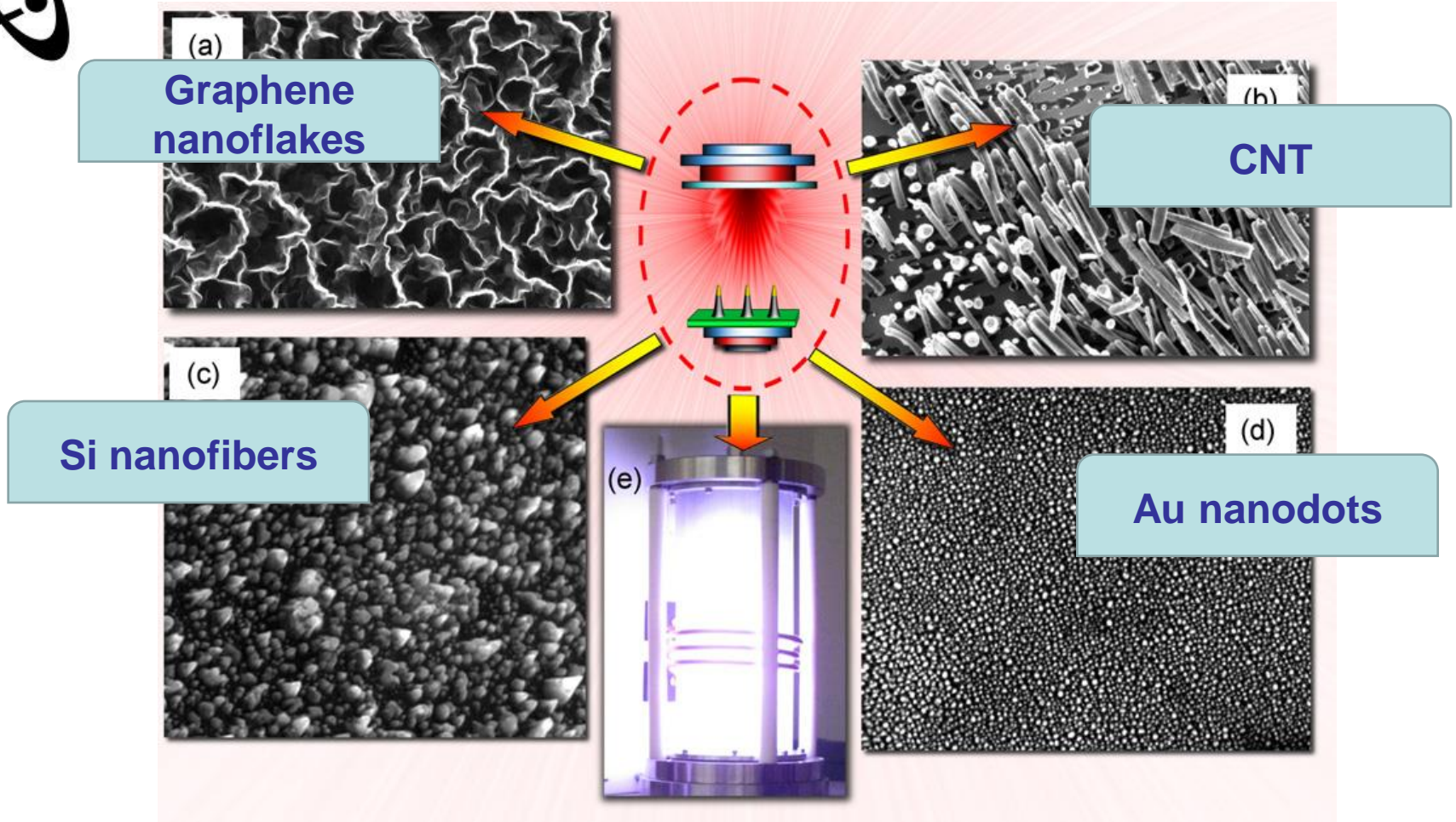


Various applications





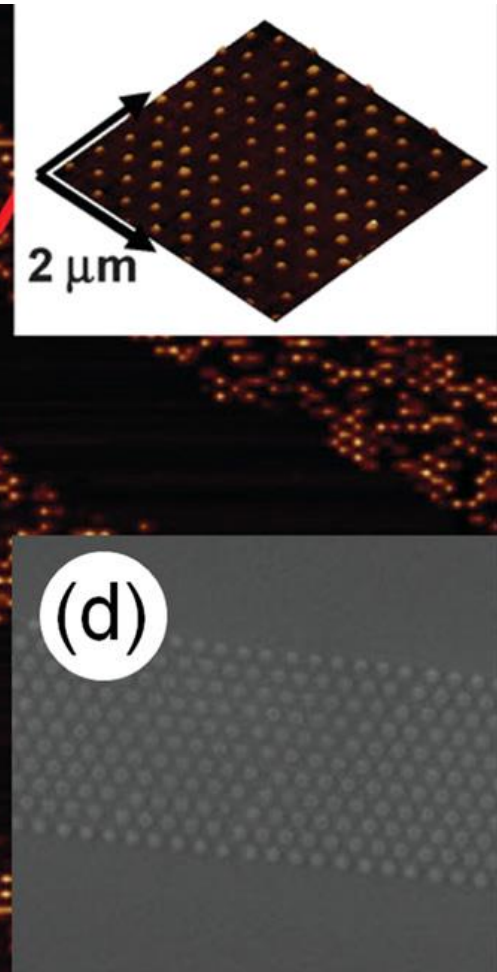
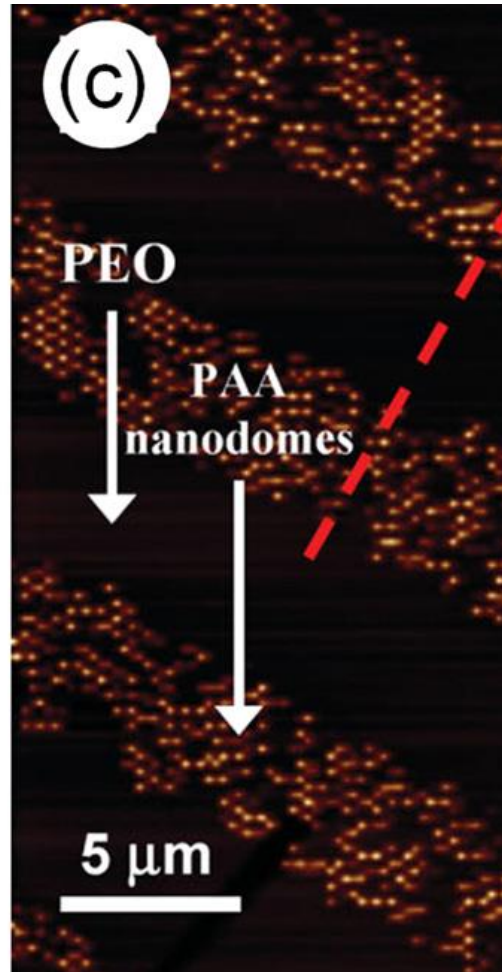
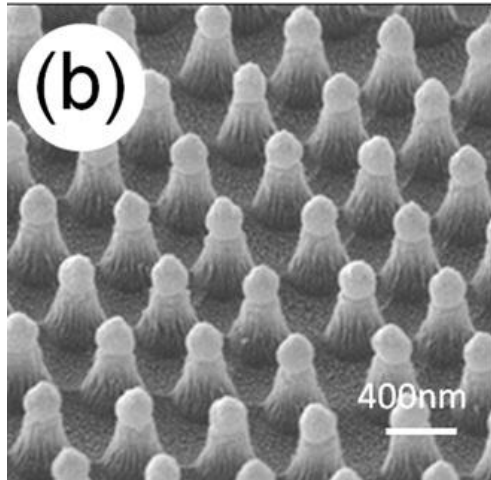
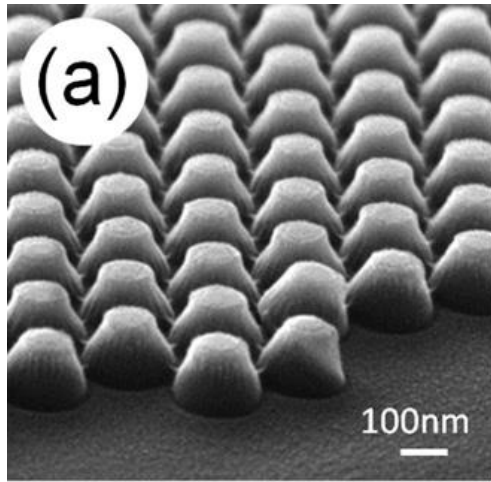
Plasma & Nanotechnology



Han et al, J. Phys. D: Appl. Phys. 44 (2011) 174019



Nano-Patterns



Ostrikov et al, J. Phys. D: Appl. Phys. 44 (2011) 174001



Challenges of plasma simulation

- The most accurate method is to solve the equation of motion of each particle in the plasma.

$$m \frac{d\vec{v}_k}{dt} = e\vec{E}_k + e\vec{v}_k \times \vec{B}_k$$

- No. of particles is very very large $n = 10^9 - 10^{13} \text{cm}^{-3}$
- Maxwell equations

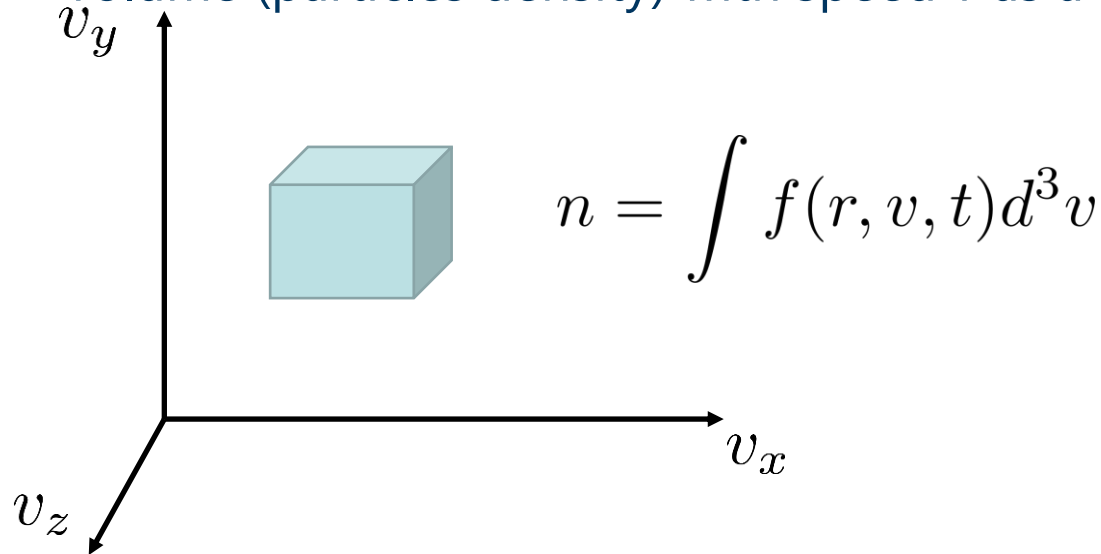
$$\begin{aligned} \vec{\nabla} \cdot \vec{D} &= \rho_v & \vec{\nabla} \times \vec{E} &= -\frac{\partial \vec{B}}{\partial t} \\ \vec{\nabla} \cdot \vec{B} &= 0 & \vec{\nabla} \times \vec{H} &= \vec{J} + \epsilon \frac{\partial \vec{E}}{\partial t} \end{aligned}$$

- The collective behaviour and the huge number of particles make the solution impossible in such way.



The distribution function

- The distribution function gives the number of particles per unit volume (particles density) with speed v as a function of time.



- The kinetic equation is an integro-differential equations in 7 parameters

$$\frac{Df}{Dt} = \frac{\partial f}{\partial t} + \vec{v} \cdot \vec{\nabla}_r f + \vec{a} \cdot \vec{\nabla}_v f = \text{collision terms}$$



Macroscopic description

- Instead of known the physical parameters of each particle, one can calculate the average values for the whole plasma system.

- Average plasma density $\bar{n} = \int f(r, v, t) d^3v$

- Average speed $\bar{v} = \int v f(r, v, t) d^3v / \bar{n}$

- Kinetic energy $\bar{E}_k = \int \frac{1}{2} m v^2 f(r, v, t) d^3v / \bar{n}$

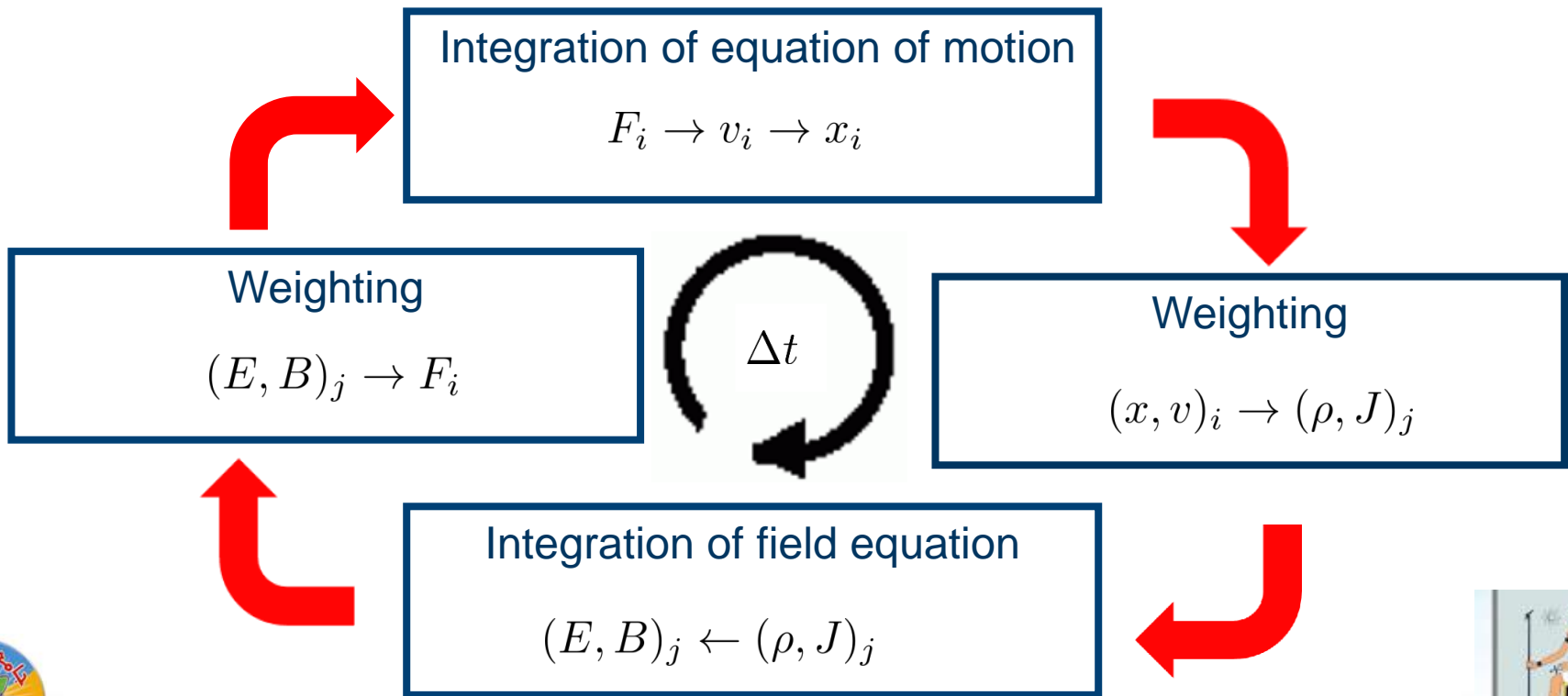
- Average over Boltzmann equation

$$m v^q \left(\frac{\partial f}{\partial t} + \vec{v} \cdot \vec{\nabla}_r f + \vec{a} \cdot \vec{\nabla}_v f \right) = \text{collision terms}$$
$$q = 0, 1, 2, 3, \dots$$



Kinetic Description

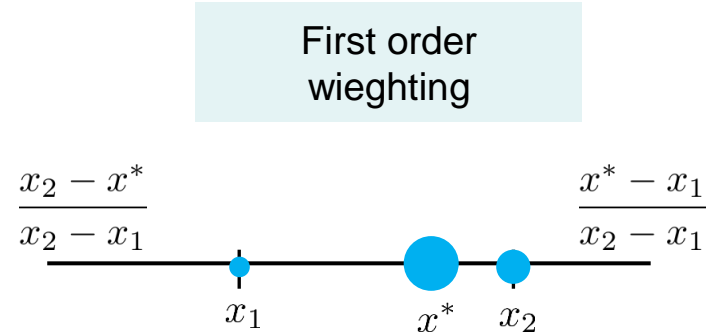
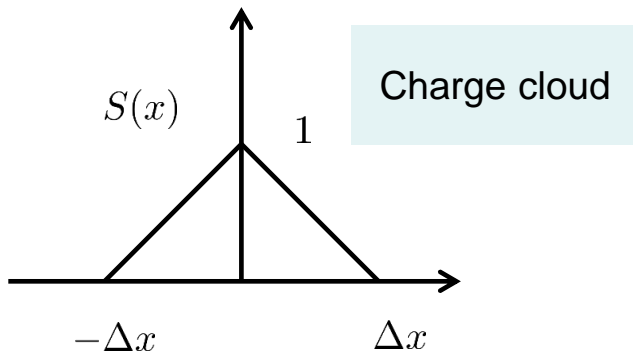
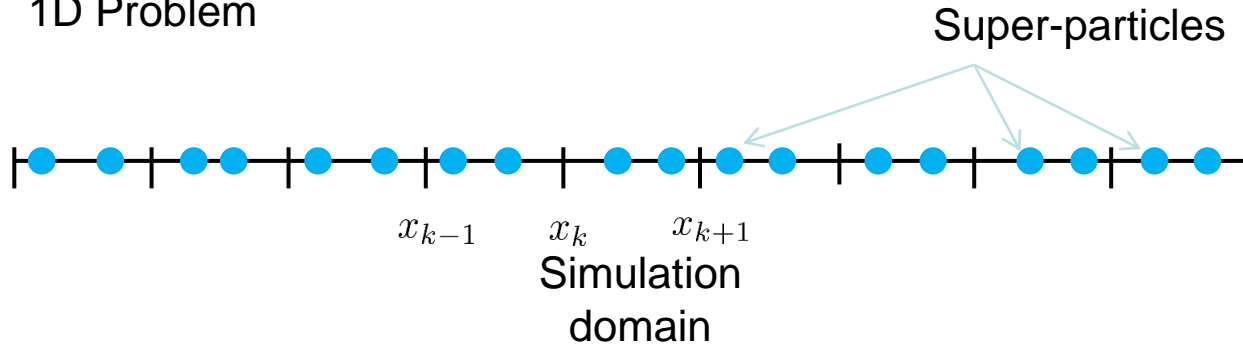
- Kinetic means „of or relating to motion“.
 - It is impractical to solve the equation of motion of all plasma particles.
 - Boltzman equation is an integro-differential equation.
- Particle-in-Cell : Super particle⁶ – 10⁹ real particles.





Particles

1D Problem





Fields

Poisson's eq.

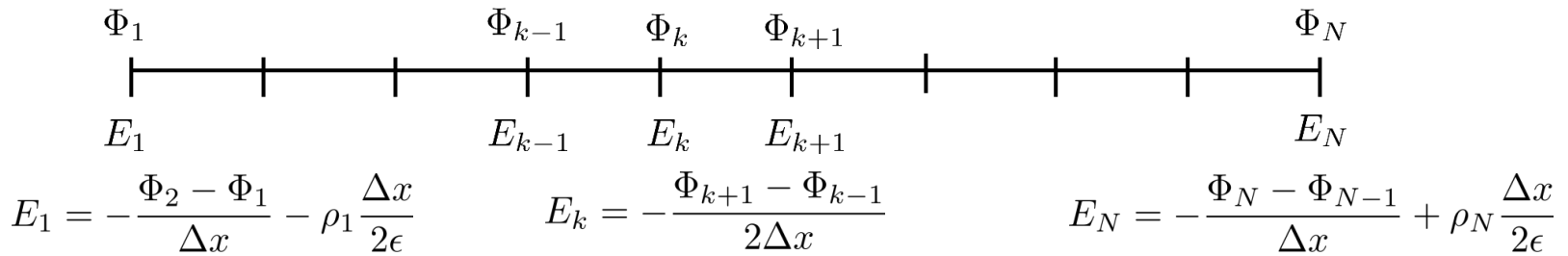
$$\nabla^2 \Phi = -\frac{\rho}{\epsilon}$$



$$\frac{\Phi_{k+1} - 2\Phi_k + \Phi_{k-1}}{\Delta x^2} = -\frac{\rho}{\epsilon}$$

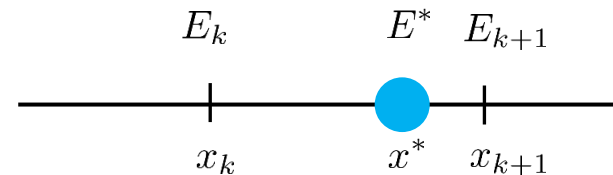
Boundary condition

Boundary condition



Interpolation of the fields to the particle positions

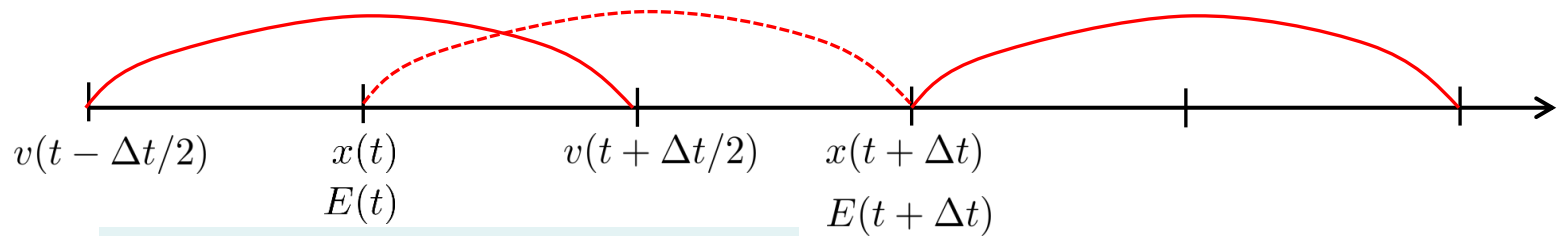
$$E^* = \frac{x^* - x_k}{\Delta x} E_{k+1} + \frac{x_{k+1} - x^*}{\Delta x} E_k$$





Pushing particles

„Leapfrog“
scheme



Descritization of equation of motions

$$\frac{v(t + \Delta t/2) - v(t - \Delta t/2)}{\Delta t} = \frac{q}{m} E(t)$$

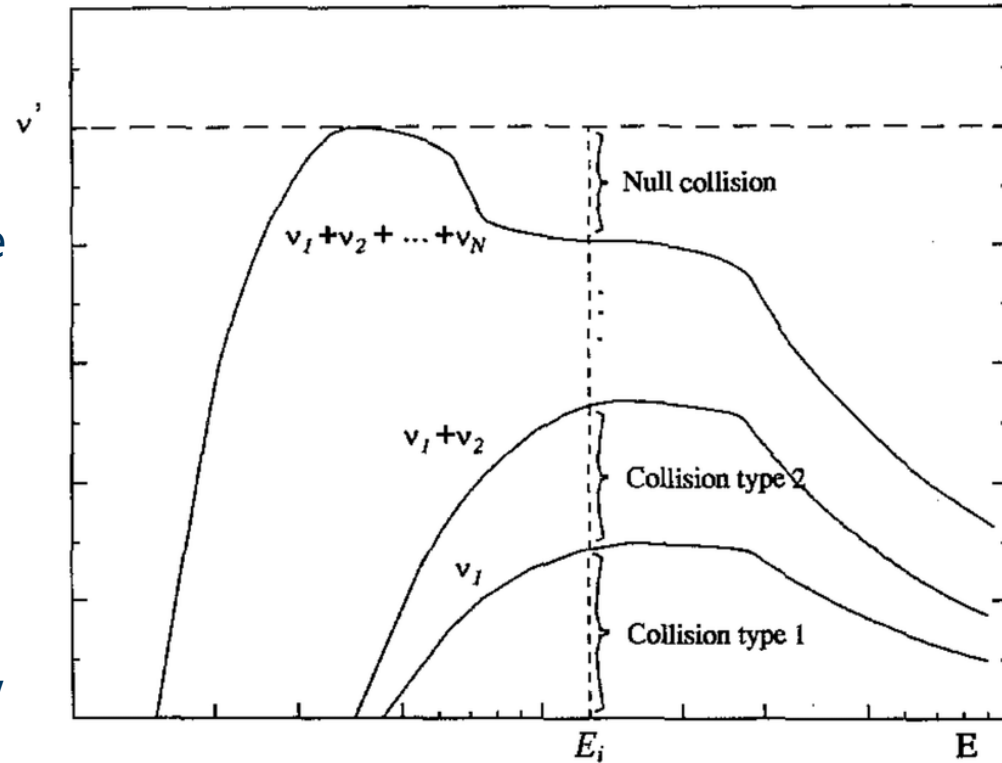
$$\frac{x(t + \Delta t) - x(t)}{\Delta t} = v(t + \Delta t/2)$$

Monte-Carlo Scheme is required for collisions



Monte Carlo: null collision method

- Many collisions take place:
impact ionization, charge exchange
hard-sphere, ...
- Let the probability of them
 $P_1, P_2, P_3, P_4, \dots$
- Calculate the total probabilities P_T
- Calculate relative probabilities
 $P_1/P_T, P_2/P_T, P_3/P_T, P_4/P_T,$



- Generate a random number between $[0,1]$
- if $P_1/P_T = < \text{The random number} < (P_1 + P_2)/P_T$
- Event 1 takes place
- If not

$(P_1 + P_2)/P_T = < \text{The random number} < (P_1 + P_2 + P_3)/P_T$



Challenges of PIC simulation

- Numerical instabilities:

- Accuracy criterion $\omega_p \Delta t \leq 0.2$

- Courant criterion $v_{\max} \Delta t \leq \Delta x$

- The computational grid has to resolve the Debye length $\Delta x \leq \lambda_D$

- In order to have a good statistics, a reasonable high number of particles per Debye length must be used $N_D \gg 1$

- Keep the probability for collisions small

$$P_{\text{coll}} = 1 - e^{-\nu t} \leq 0.1$$

- Alternatives:

- Implicit schemes

- Parrallilization



Fluid Models

- Continuity, momentum, and energy equations are closed with Poisson's equation



$$\frac{\partial n_{e,i,m}}{\partial t} + \vec{\nabla} \cdot \vec{\Gamma}_{e,i,m} = G_{e,i,m} - L_{e,i,m},$$

$$\vec{\Gamma}_{e,i,m} = \text{sign}(q_{e,i,m}) n_{e,i,m} \mu_{e,i,m} \vec{E} - D_{e,i,m} \vec{\nabla} n_{e,i,m},$$

$$\frac{\partial n_e T_e}{\partial t} = -\vec{\nabla} \cdot \left(\frac{5}{3} T_e \vec{\Gamma}_e - \frac{5}{3} n_e D_e \vec{\nabla} T_e \right) - e \vec{\Gamma}_e \cdot \vec{E} - n_e n_G k_{\text{loss}},$$

and

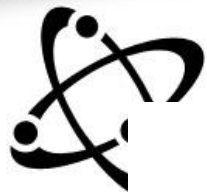
$$T_i = T_m = 0.026 \text{ eV}.$$



Fluid Models

Ar atomic processes considered in the simulation

Equation of Reaction	Rate of Reaction Coefficient	
$e + \text{Ar} \rightarrow \text{Ar}^+ + 2e$	impact-ionization	$K_{ei} = 1.253 \times 10^{-7} \exp(-18.618/T_e) \text{ cm}^3/\text{s}$
$e + \text{Ar} \rightarrow \text{Ar}^* + e$	collisional-excitation	$K_{ex} = 3.712 \times 10^{-8} \exp(-15.06/T_e) \text{ cm}^3/\text{s}$
$e + \text{Ar}^* \rightarrow \text{Ar}^+ + 2e$	impact-ionization	$K_{mi} = 2.05 \times 10^{-7} \exp(-4.95/T_e) \text{ cm}^3/\text{s}$
$e + \text{Ar}^* \rightarrow \text{Ar} + e$	collisional-deexcitation	$K_{em} = 1.818 \times 10^{-9} \exp(-2.14/T_e) \text{ cm}^3/\text{s}$
$e + \text{Ar}^* \rightarrow \text{Ar}^r + e$	radiative-deexcitation	$K_r = 2 \times 10^{-7} \text{ cm}^3/\text{s}$
$\text{Ar}^* + \text{Ar}^* \rightarrow \text{Ar}^+ + \text{Ar} + e$	collisional-ionization	$K_{mm} = 6.2 \times 10^{-10} \text{ cm}^3/\text{s}$
$\text{Ar}^* + \text{Ar} \rightarrow 2\text{Ar}$	collisional-deexcitation	$K_{2q} = 3.0 \times 10^{-15} \text{ cm}^3/\text{s}$
$\text{Ar}^* + 2\text{Ar} \rightarrow \text{Ar} + \text{Ar}_2$	attachment	$K_{3q} = 1.1 \times 10^{-31} \text{ cm}^6/\text{s}$



Main reactions and the corresponding rate coefficients in the Ar/CF₄ discharge plasma.

Reaction equation	Reaction rate coefficient
$\text{CF}_3^- + \text{Ar}^+ \rightarrow \text{CF}_3 + \text{Ar}$	$1 \times 10^{-7} \text{ cm}^3 \text{ s}^{-1}$
$\text{F}^- + \text{Ar}^+ \rightarrow \text{F} + \text{Ar}$	$1 \times 10^{-7} \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_4 + \text{Ar}^+ \rightarrow \text{CF}_3^+ + \text{F} + \text{Ar}$	$9.58 \times 10^{-10} \text{ cm}^3 \text{ s}^{-1}$
$\text{Ar} + \text{CF}_3^+ \rightarrow \text{CF}_3 + \text{Ar}^+$	$1 \times 10^{-9} \text{ cm}^3 \text{ s}^{-1}$

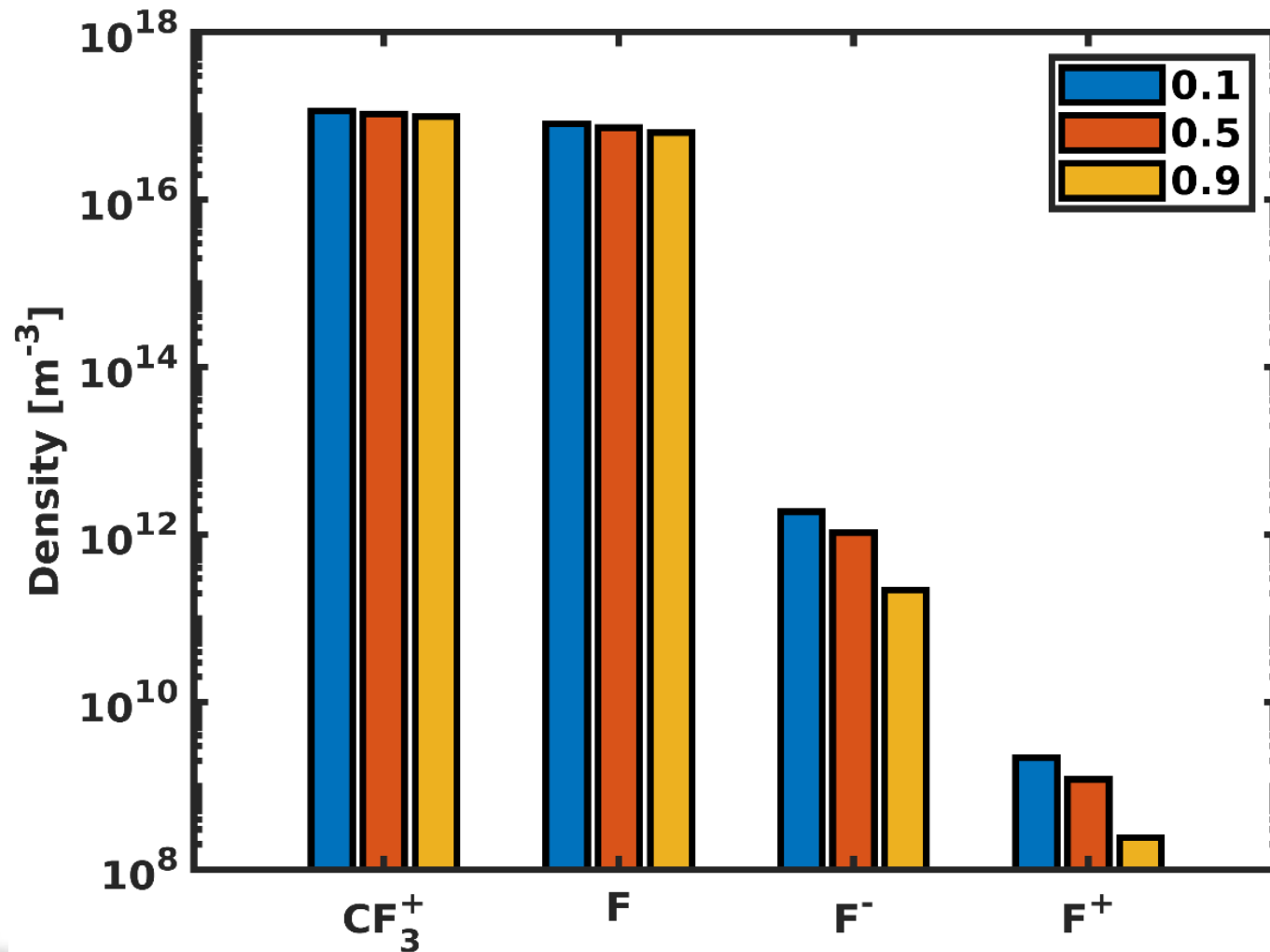
Chengjie Bai *et al* 2018 *J. Phys. D: Appl. Phys.* 51 255201



Reaction equation	Reaction rate coefficient
$\text{CF}_4 + e \rightarrow \text{CF}_4^+ + 2e$	Calculated by BOLSIG+
$\text{CF}_3 + e \rightarrow \text{CF}_3^+ + 2e$	$1.4 \times 10^{-11} (11605 \times T_e)^{0.6481} \exp(-9.8/T_e) \text{ cm}^3 \text{ s}^{-1}$
$\text{F} + e \rightarrow \text{F}^+ + 2e$	$7.489 \times 10^{-13} (11605 \times T_e)^{0.8595} \exp(-17.6/T_e) \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_4 + e \rightarrow \text{CF}_4^*(12.5 \text{ eV}) + e$	Calculated by BOLSIG+
$\text{CF}_4 + e \rightarrow \text{CF}_4^*(8 \text{ eV}) + e$	Calculated by BOLSIG+
$\text{CF}_4 + e \rightarrow \text{CF}_4(\text{V13}) + e$	Calculated by BOLSIG+
$\text{CF}_4 + e \rightarrow \text{CF}_4(\text{V24}) + e$	Calculated by BOLSIG+
$\text{CF}_4 + e \rightarrow \text{CF}_3^+ + \text{F} + 2e$	$1.159 \times 10^{-11} (11605 \times T_e)^{0.7645} \exp(-17.2/T_e) \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_4 + e \rightarrow \text{CF}_2^+ + \text{F}_2 + 2e$	$2.886 \times 10^{-11} (11605 \times T_e)^{0.5108} \exp(-22.8/T_e) \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_4 + e \rightarrow \text{CF}^+ + \text{F}_2 + \text{F} + 2e$	$2.296 \times 10^{-14} (11605 \times T_e)^{1.09} \exp(-27.0/T_e) \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_4 + e \rightarrow \text{CF}_3 + \text{F}^+ + 2e$	$1.482 \times 10^{-13} (11605 \times T_e)^{0.9375} \exp(-34.7/T_e) \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_4 + e \rightarrow \text{CF}_3 + \text{F} + e$	$2 \times 10^{-9} \exp(-13/T_e) \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_4 + e \rightarrow \text{CF}_2 + 2\text{F} + e$	$5 \times 10^{-9} \exp(-13/T_e) \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_3 + \text{F}^- \rightarrow \text{CF}_4 + e$	$5 \times 10^{-10} \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_2 + \text{F}^- \rightarrow \text{CF}_3 + e$	$5 \times 10^{-10} \text{ cm}^3 \text{ s}^{-1}$
$\text{CF} + \text{F}^- \rightarrow \text{CF}_2 + e$	$5 \times 10^{-10} \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_3 + \text{F} \rightarrow \text{CF}_4$	$2 \times 10^{-11} \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_2 + \text{F} \rightarrow \text{CF}_3$	$1.3 \times 10^{-11} \text{ cm}^3 \text{ s}^{-1}$
$\text{CF} + \text{F} \rightarrow \text{CF}_2$	$5.2 \times 10^{-15} \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_3^- + \text{CF}_3^+ \rightarrow 2\text{CF}_3$	$4 \times 10^{-7} \text{ cm}^3 \text{ s}^{-1}$
$\text{F}^- + \text{CF}_3^+ \rightarrow \text{F} + \text{CF}_3$	$4 \times 10^{-7} \text{ cm}^3 \text{ s}^{-1}$
$\text{F}^- + \text{CF}_2^+ \rightarrow \text{F} + \text{CF}_2$	$1 \times 10^{-7} T_g^{-0.5} \text{ cm}^3 \text{ s}^{-1}$
$\text{F}^- + \text{CF}^+ \rightarrow \text{F} + \text{CF}$	$1 \times 10^{-7} T_g^{-0.5} \text{ cm}^3 \text{ s}^{-1}$
$\text{F}^- + \text{F}^+ \rightarrow \text{F}_2$	$4 \times 10^{-7} T_g^{-0.5} \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_2^+ + e \rightarrow \text{CF} + \text{F}$	$4 \times 10^{-8} \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}^+ + e \rightarrow \text{C} + \text{F}$	$4 \times 10^{-8} \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_3^+ + e \rightarrow \text{CF}_3$	$9.6 \times 10^{-7} \text{ cm}^3 \text{ s}^{-1}$
$\text{F}^+ + e \rightarrow \text{F}$	$4 \times 10^{-8} \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_4^+ \rightarrow \text{CF}_3^+ + \text{F}$	$3.3 \times 10^5 \text{ s}^{-1}$
$\text{CF}_4 + e \rightarrow \text{CF}_3 + \text{F}^-$	$4.8 \times 10^{-12} \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_4 + e \rightarrow \text{CF}_3^- + \text{F}$	$3.28 \times 10^{-11} \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_2 + \text{F}_2 \rightarrow \text{CF}_3 + \text{F}$	$4.56 \times 10^{-13} \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_3 + \text{F}_2 \rightarrow \text{CF}_4 + \text{F}$	$1.88 \times 10^{-14} \text{ cm}^3 \text{ s}^{-1}$
$\text{CF}_3^- + \text{F} \rightarrow \text{CF}_3 + \text{F}^-$	$5 \times 10^{-8} \text{ cm}^3 \text{ s}^{-1}$
$2\text{CF}_4^*(12.5 \text{ eV}) \rightarrow 2\text{CF}_4$	$4.9 \times 10^{-4} \text{ cm}^3 \text{ s}^{-1}$
$2\text{CF}_4^*(8 \text{ eV}) \rightarrow 2\text{CF}_4$	$4.9 \times 10^{-4} \text{ cm}^3 \text{ s}^{-1}$
$2\text{CF}_4(\text{V13}) \rightarrow 2\text{CF}_4$	$4.9 \times 10^{-4} \text{ cm}^3 \text{ s}^{-1}$
$2\text{CF}_4(\text{V24}) \rightarrow 2\text{CF}_4$	$4.9 \times 10^{-4} \text{ cm}^3 \text{ s}^{-1}$



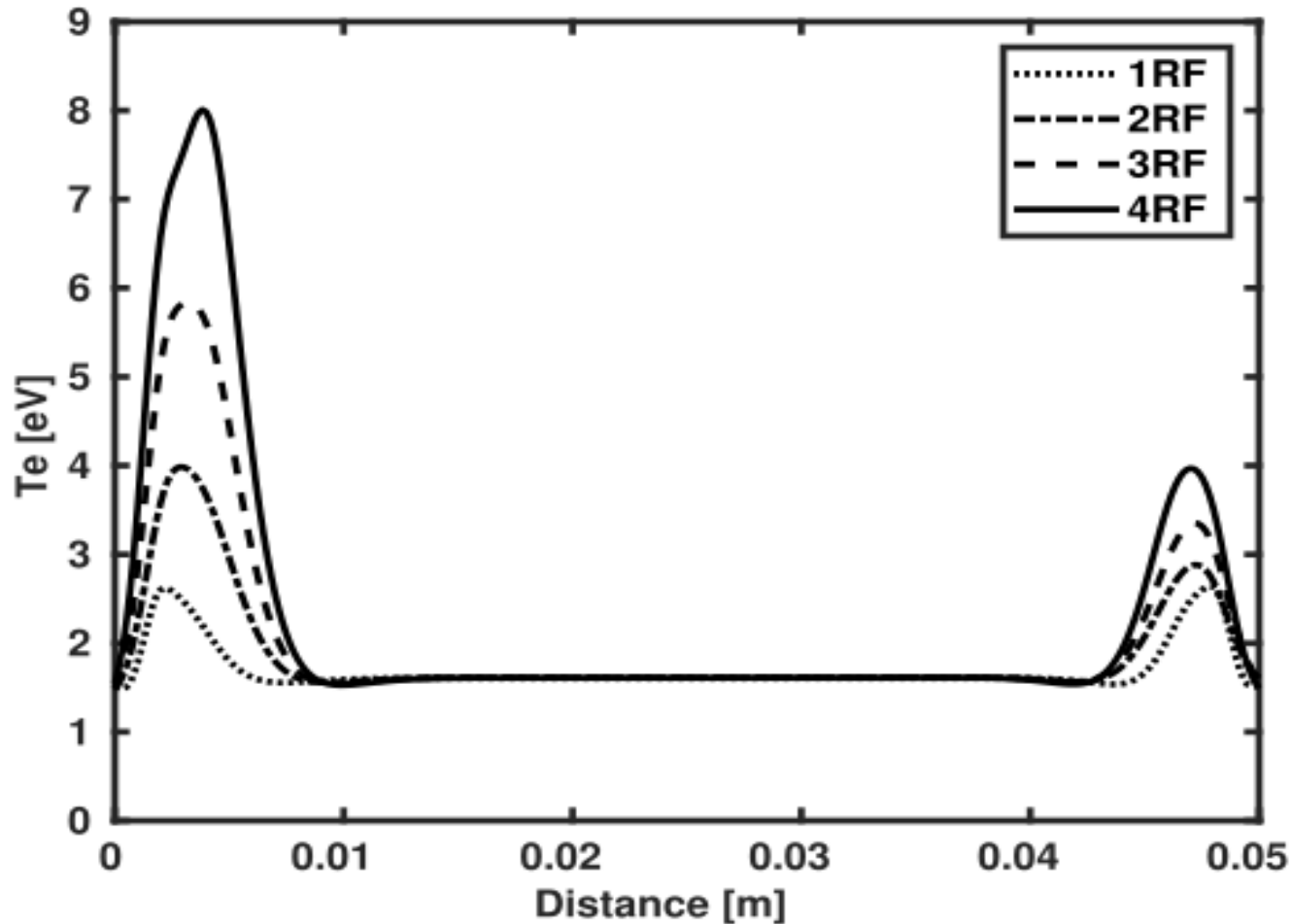
The effect of Ar ratios





The electron temperature

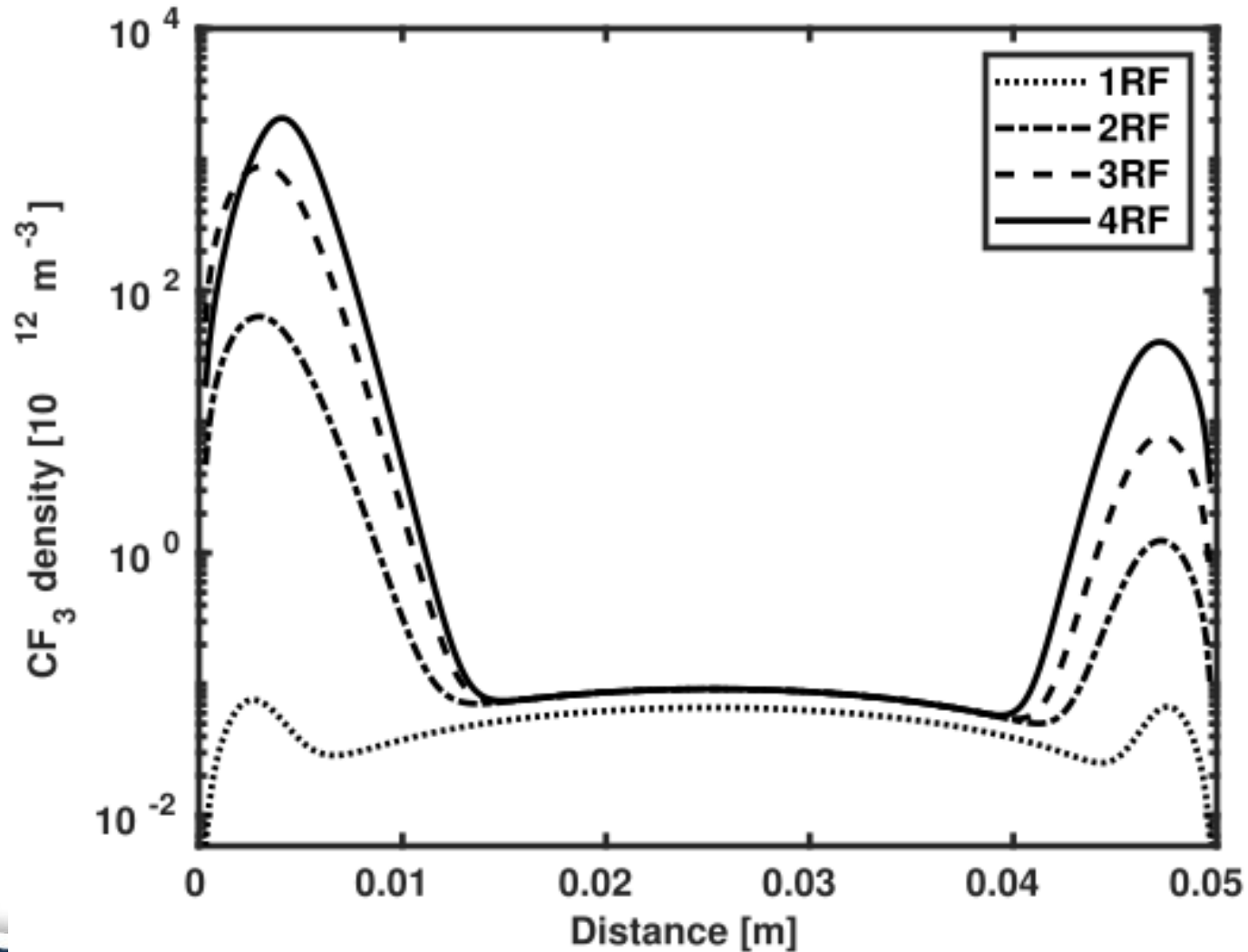
Fundamental frequency=13.56MHz

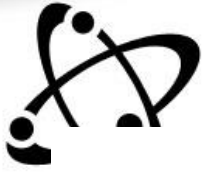




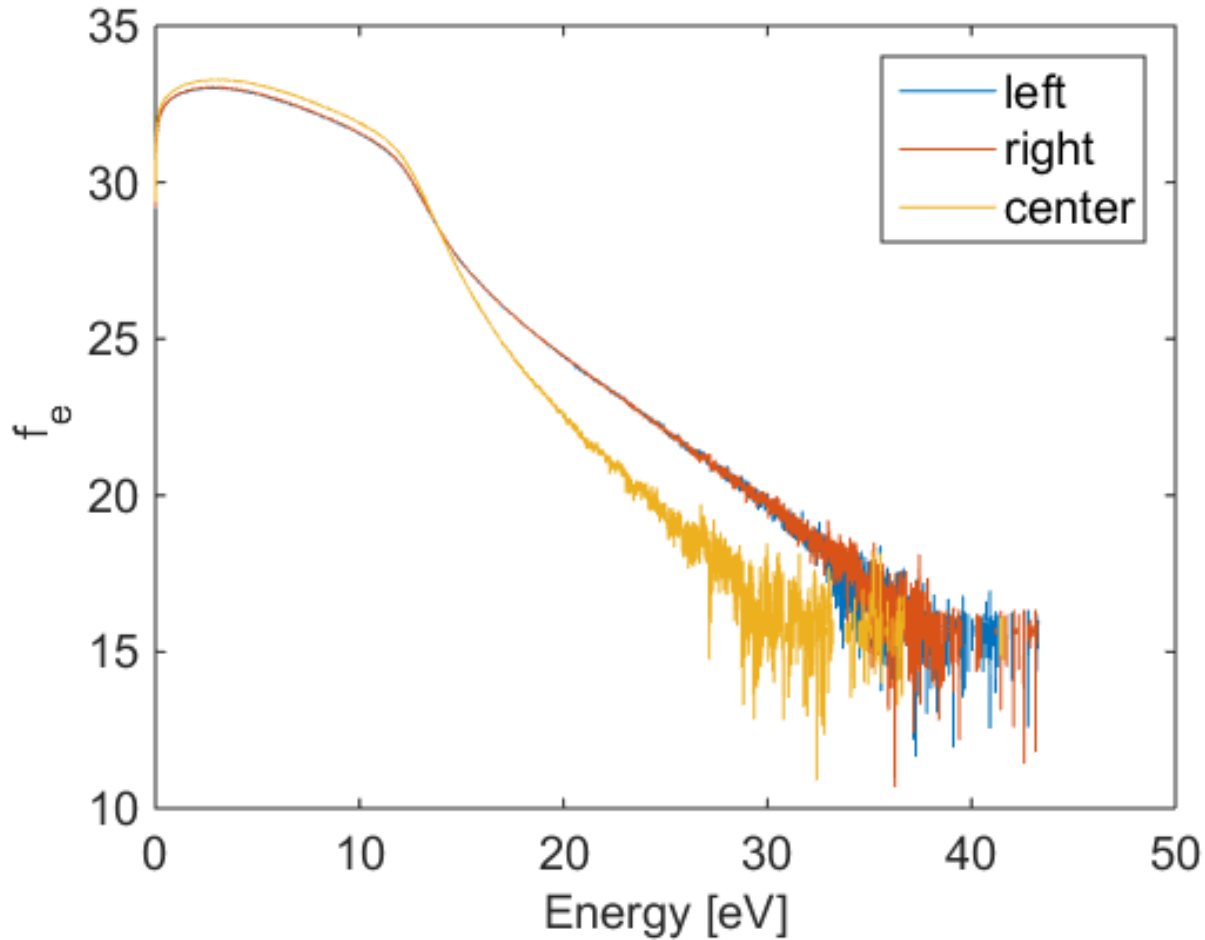
The density of CF₃ Species

Fundamental frequency=13.56MHz





Kinetic Confirmation-Symmetric discharge

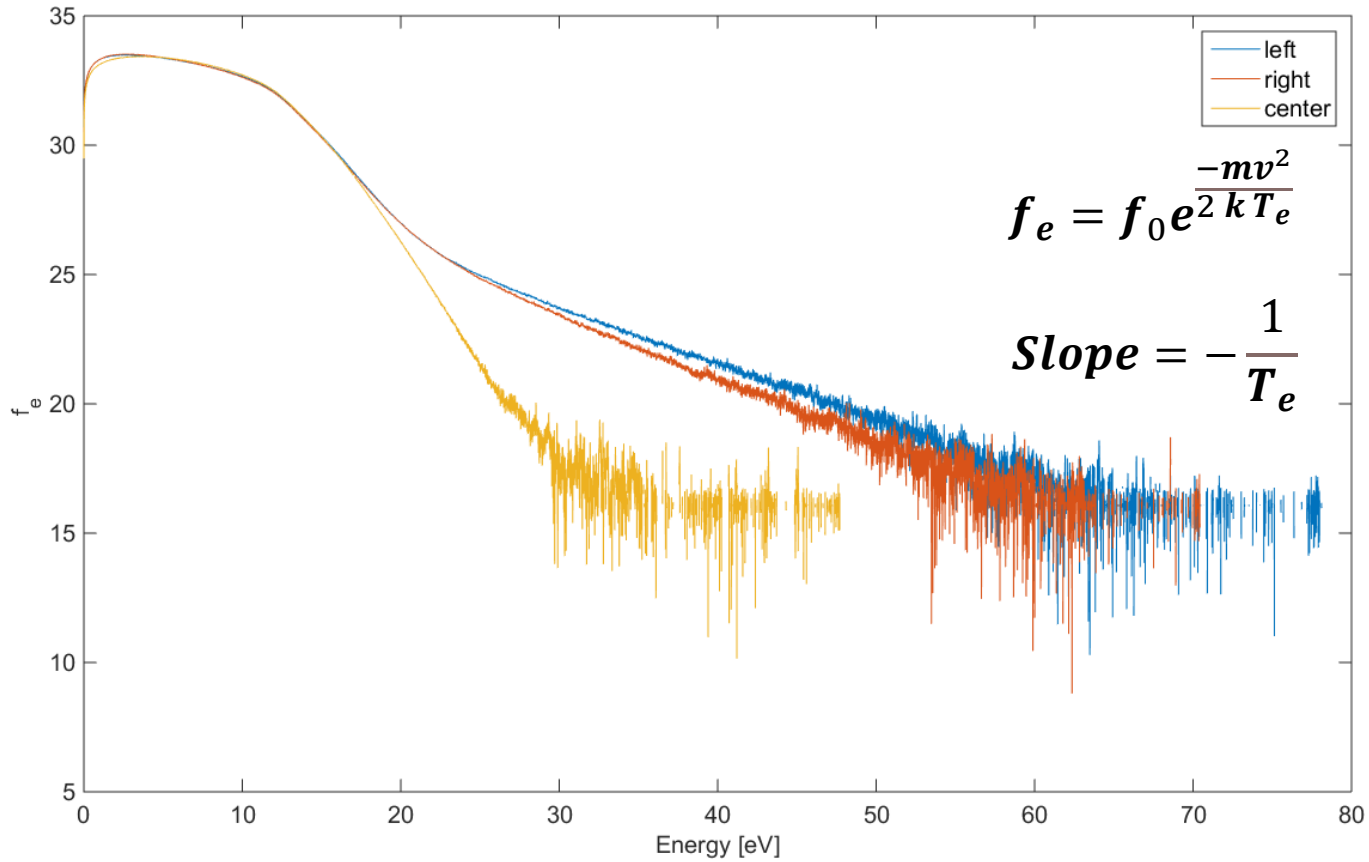


$$f_e = f_0 e^{\frac{-mv^2}{2kT_e}}$$

$$Slope = -\frac{1}{T_e}$$

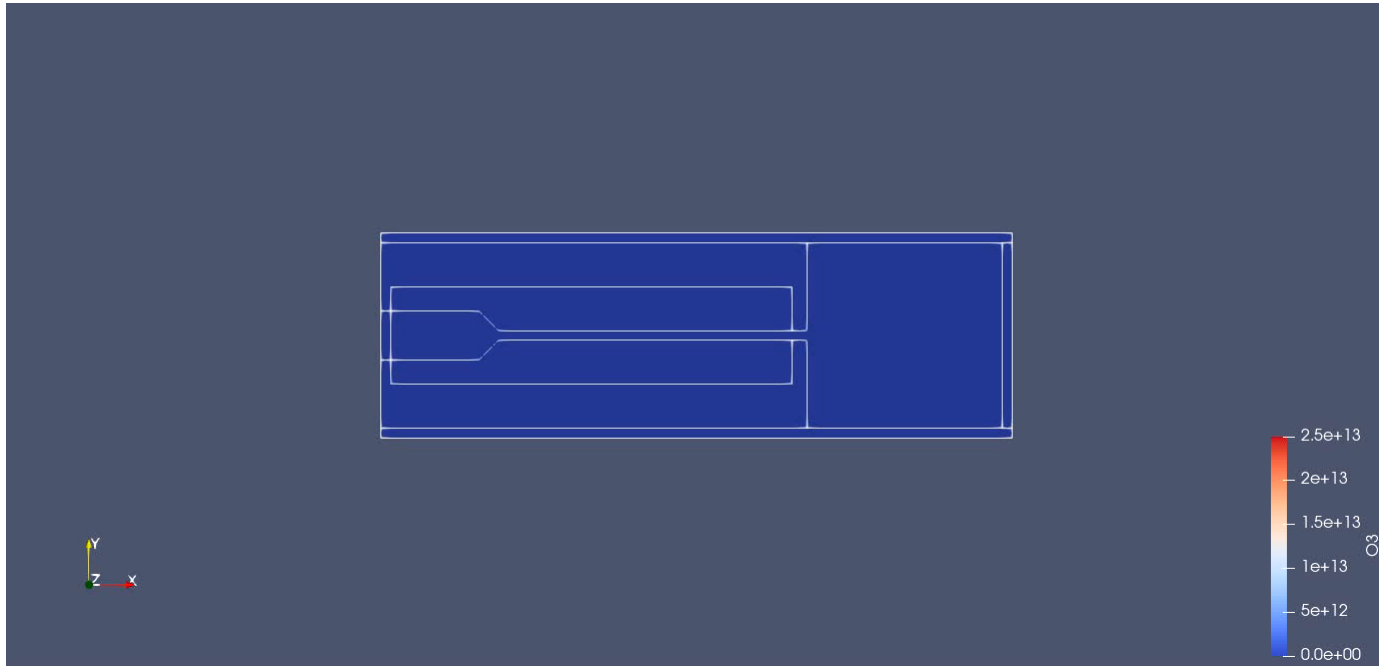


Kinetic Confirmation-Asymmetric discharge





Plasma Jets



Ruhr-Universität Bochum
Fakultät für Elektrotechnik und Informationstechnik
Lehrstuhl für Angewandte Elektrodynamik und Plasmatechnik
(AEPT)





Global model: Zero dimensional model

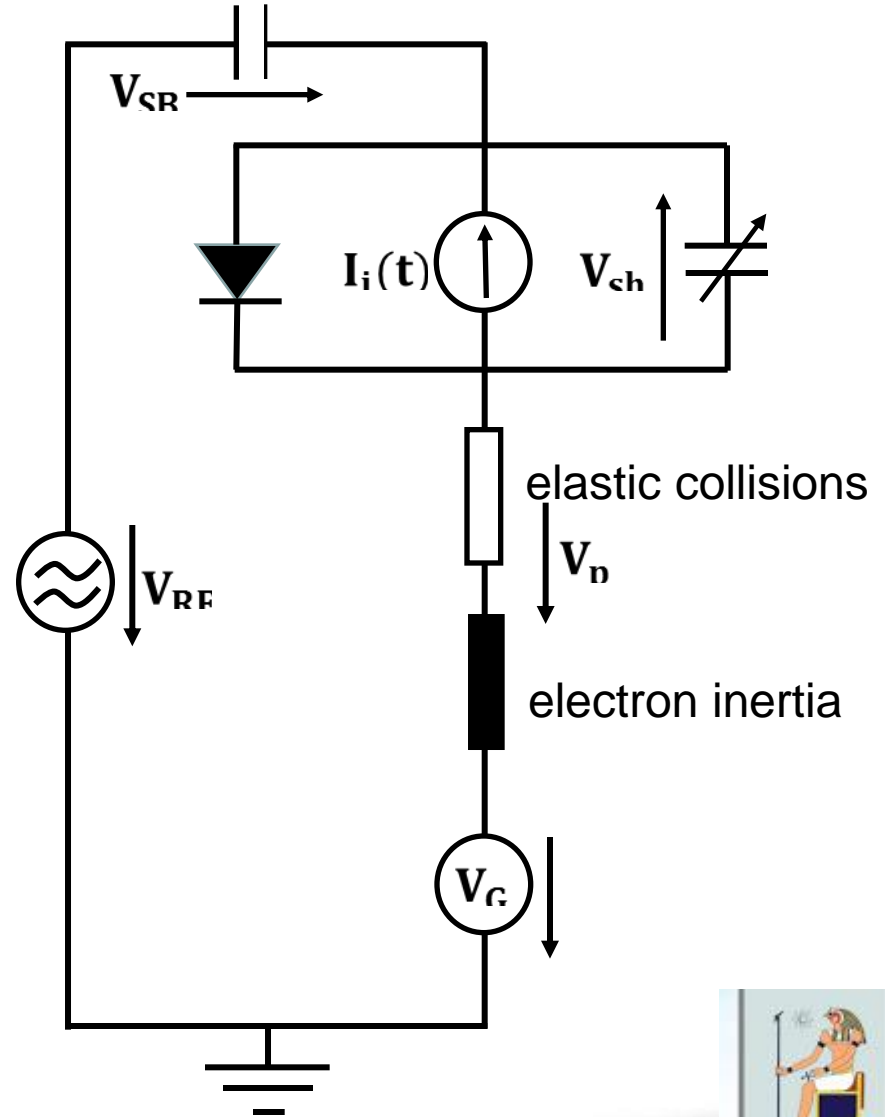
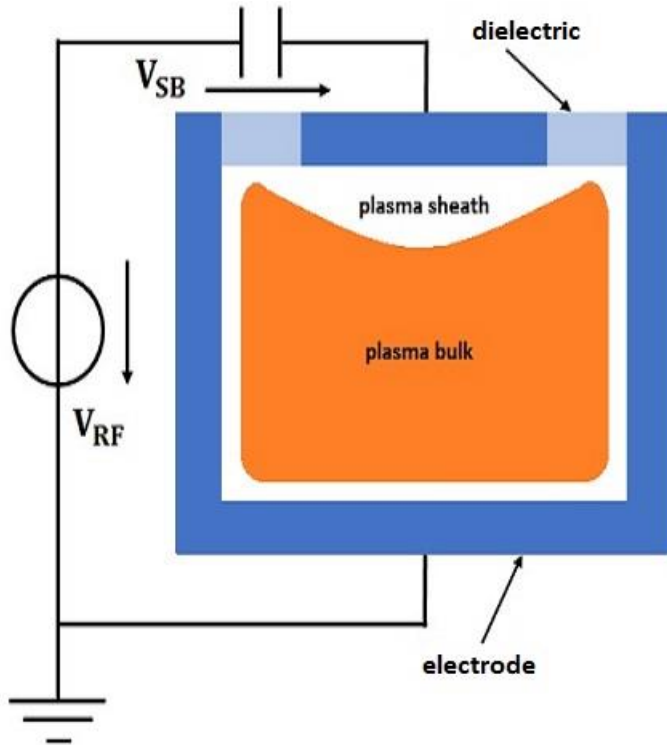
$$\frac{\partial n_e}{\partial t} = n_e n_s k_i - n_e n_s k_r - \text{loss term}$$

Note

- **If right hand side always positive = Simulation diverge with time**
- **If right hand side always negative = the plasma density vanishes with time**
- **We are looking for balance situation. Comparison with experiments is highly required.**



Global model: Electrical circuit



M. Shihab / Physics Letters A 382 (2018) 1609–1614



Model equations

$$\frac{dQ(t)}{dt} = -I - en_s(t)A_s u_s(t) + en_B \sqrt{(T_e/2\pi m_e)} A_s \exp(-eV_s(t)/T_e)$$

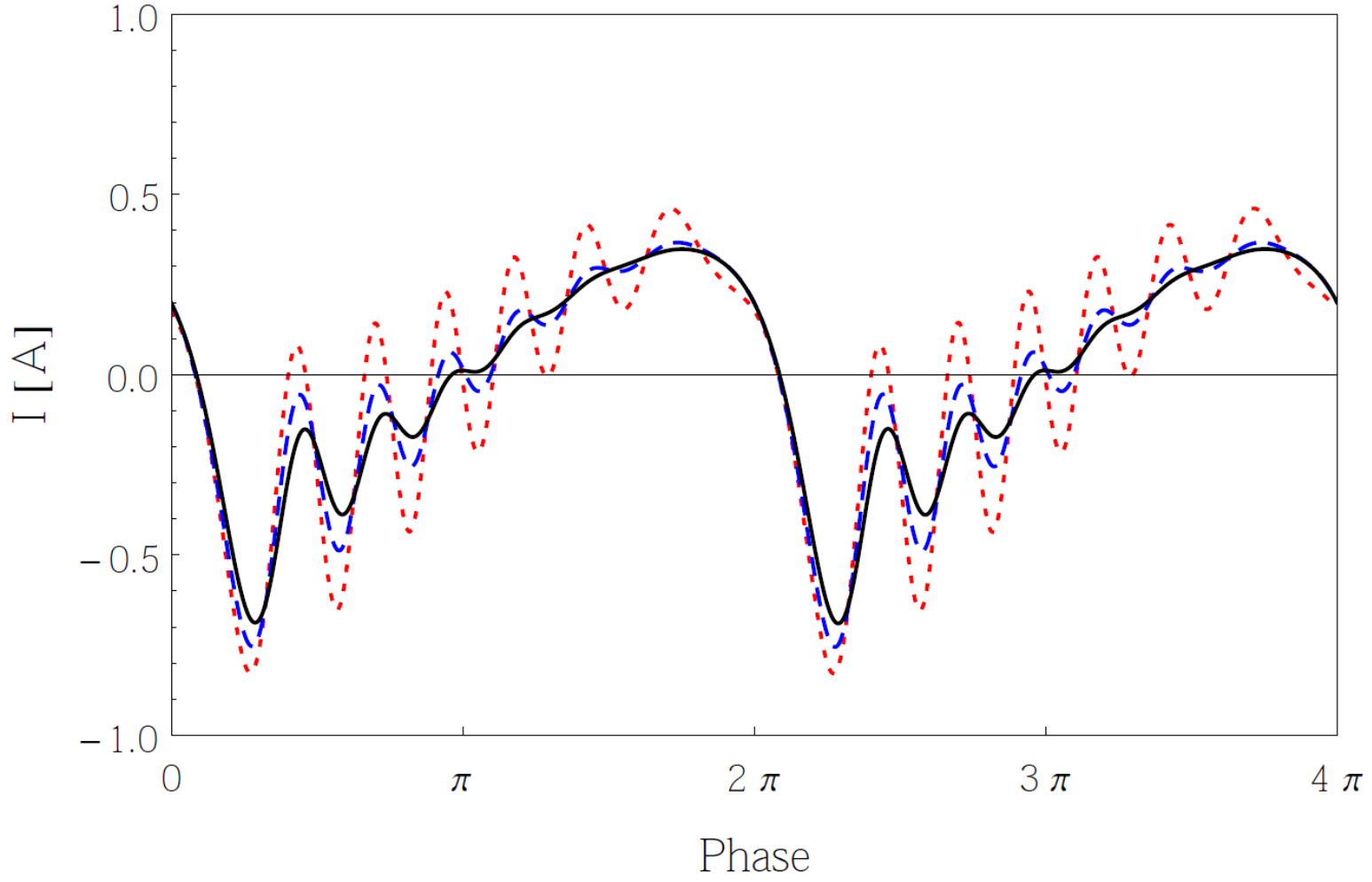
$$V_s(t) = \frac{Q^2(t)}{2\epsilon_0 en_s(t) A_s^2}$$

$$\frac{m_e L_B}{e^2 n_B A_B} \left(\frac{dI(t)}{dt} + \nu_{\text{eff}} I(t) \right) = V_s(t) - V_G - V_{\text{SB}}(t) + V_{\text{RF}}(t)$$

$$V_G = \frac{T_e}{2e} \ln\left(\frac{m_i}{2\pi m_e}\right)$$

$$C \frac{dV_{\text{SB}}(t)}{dt} = I(t)$$

$$P(t) = \frac{m_e L_B}{e^2 n_B A_B} \nu_{\text{eff}} I^2(t) \quad \bar{P}(t) = \frac{m_e L_B}{e^2 n_B A_B \tau} \int_0^t \nu_{\text{eff}} I^2(t) dt$$



■ 50 mTorr Black, 30 mTorr Blue, 10 mTorr Red
■ 3.56 MHz



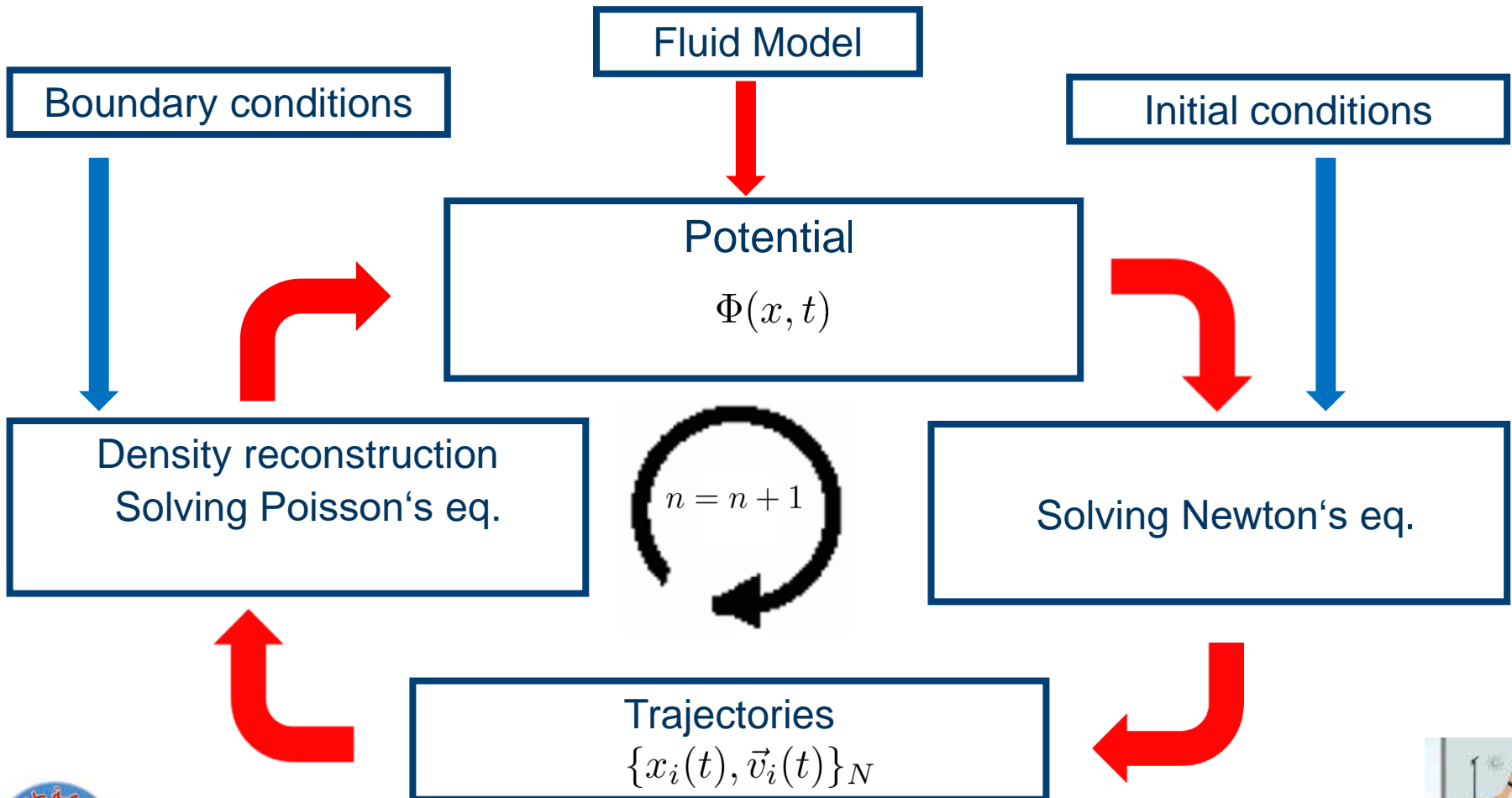


Ensemble-in-Spacetime Kinetic Sheath model





Ensemble in Spacetime

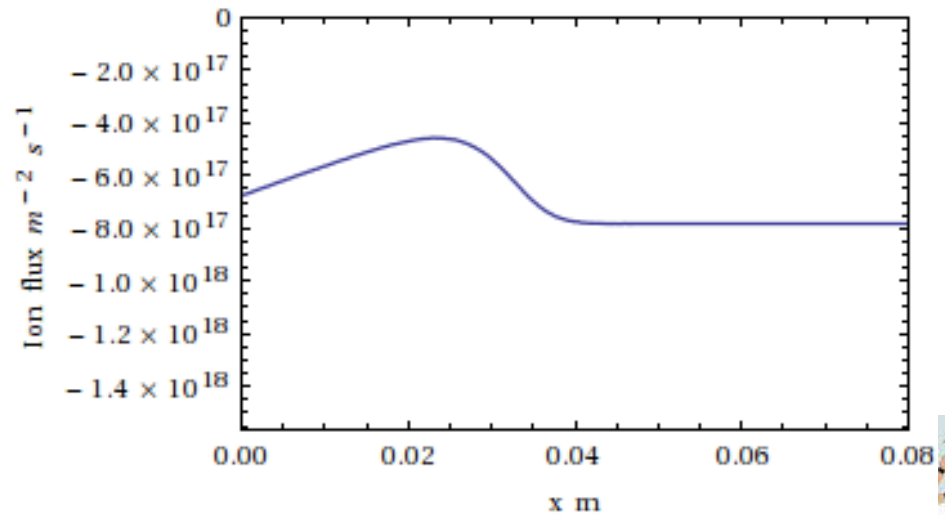
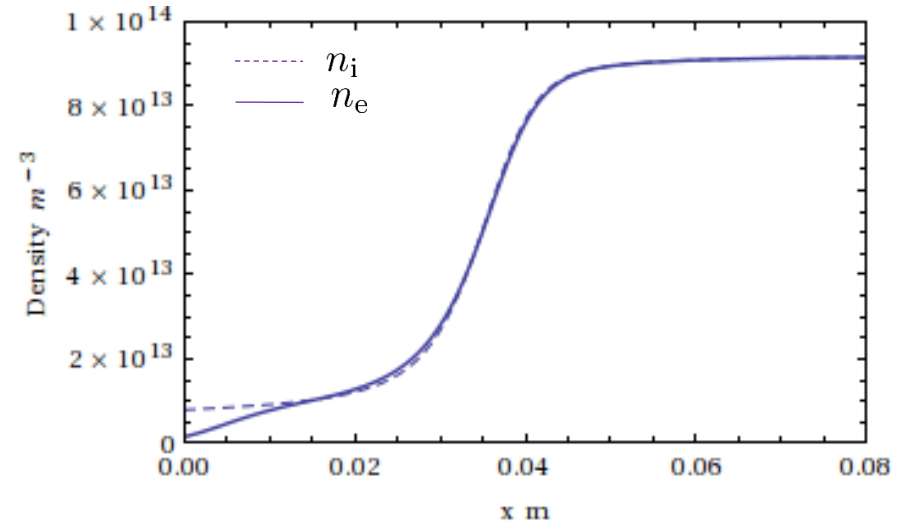




Ion dynamics

- The intermediate regime

$$\omega_{RF} \approx \omega_{pi}$$

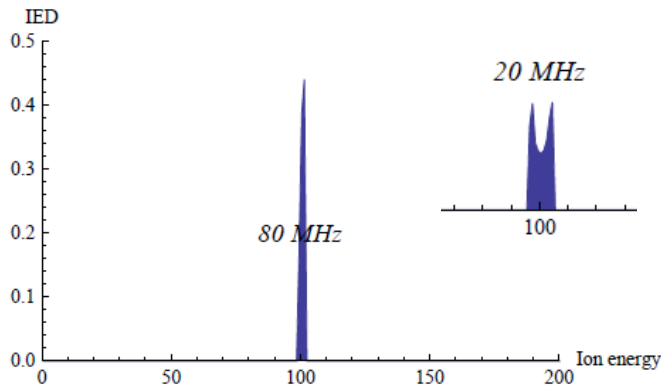




IEDFs

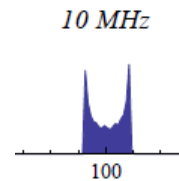
- HF regime

$$\omega_{RF} \gg \omega_{pi}$$



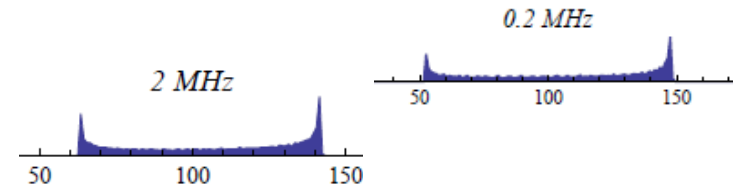
- IMF regime

$$\omega_{RF} \approx \omega_{pi}$$



- LF regime

$$\omega_{RF} \ll \omega_{pi}$$



Argon plasma $n_i = 10^{10} \text{ cm}^{-3}$

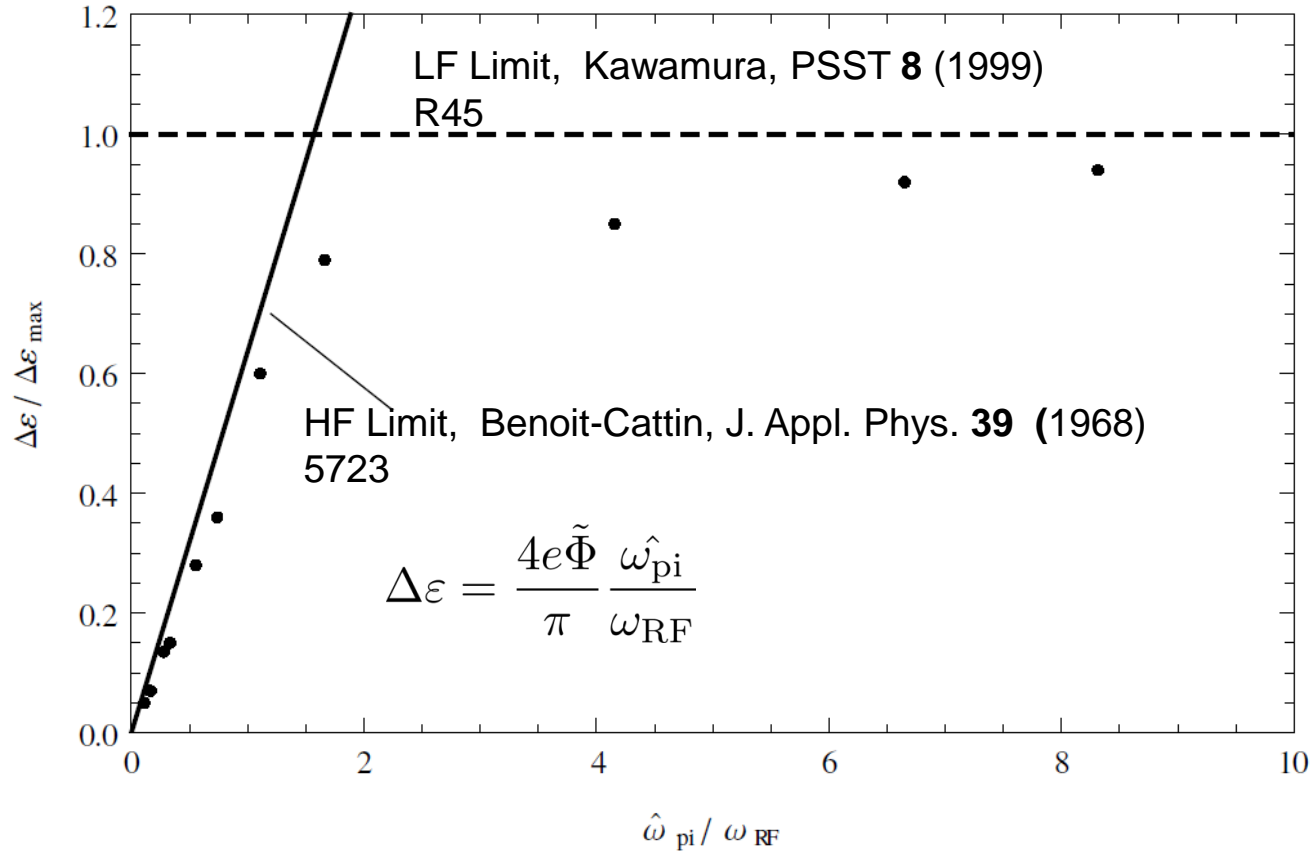


Verification of the EST Model





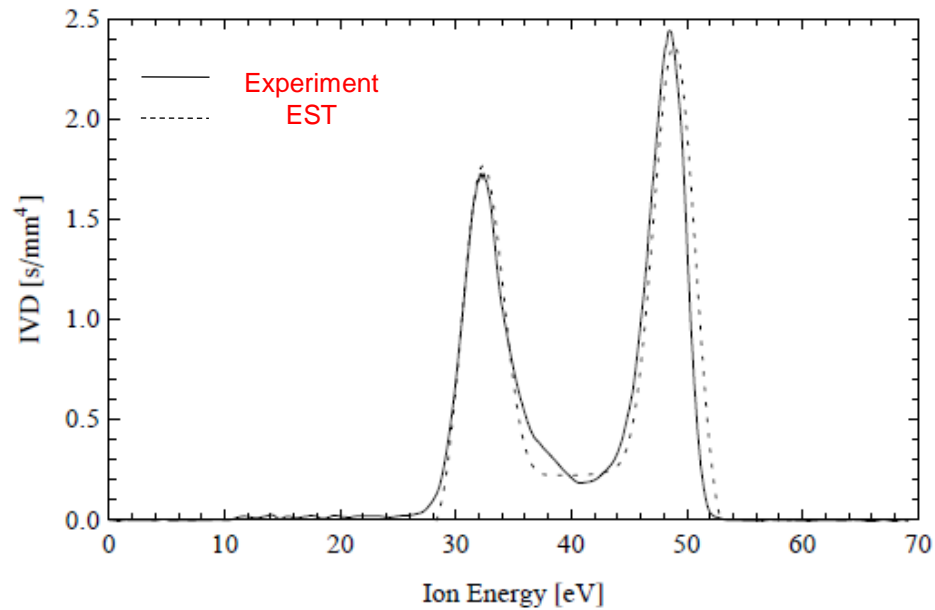
Compare to analytical models



M. Shihab et al, J. Phys.D: Appl. Phys.**45** (2012) 185202



Comparison to experiment



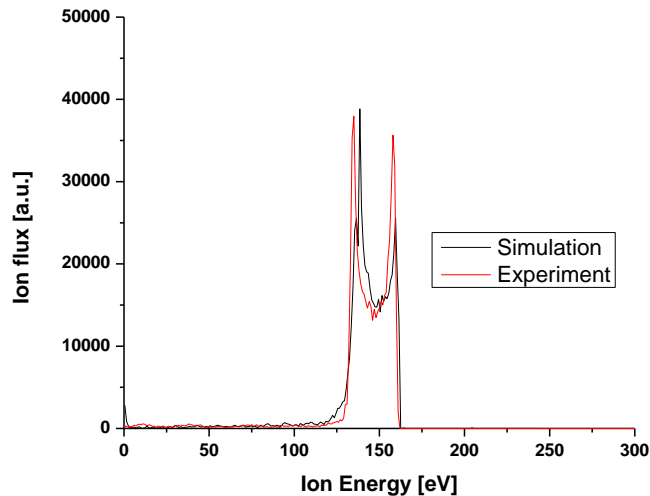
T. Baloniak et al J. Phys. D: Appl. Phys. **43** 335201 2010

M. Shihab et al. 30th ICPIG, Belfast, UK, 2011

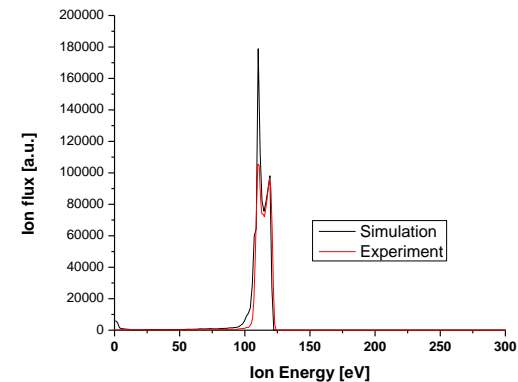


Simulation vs Experiment (privat)

27 MHz, 86 mTorr, 0.2 mA cm^{-2} ,
CHF₂⁺ in Ar, Te=4eV



60 MHz, 86 mTorr, 0.2 mA cm^{-2} ,
CHF₂⁺ in Ar, Te=4eV



- The same species under the same conditions except the driven RF frequency.
- Decreasing the driven RF frequencies leads to shorter ion transit times with respect to the driven RF period and consequently a wider IED.



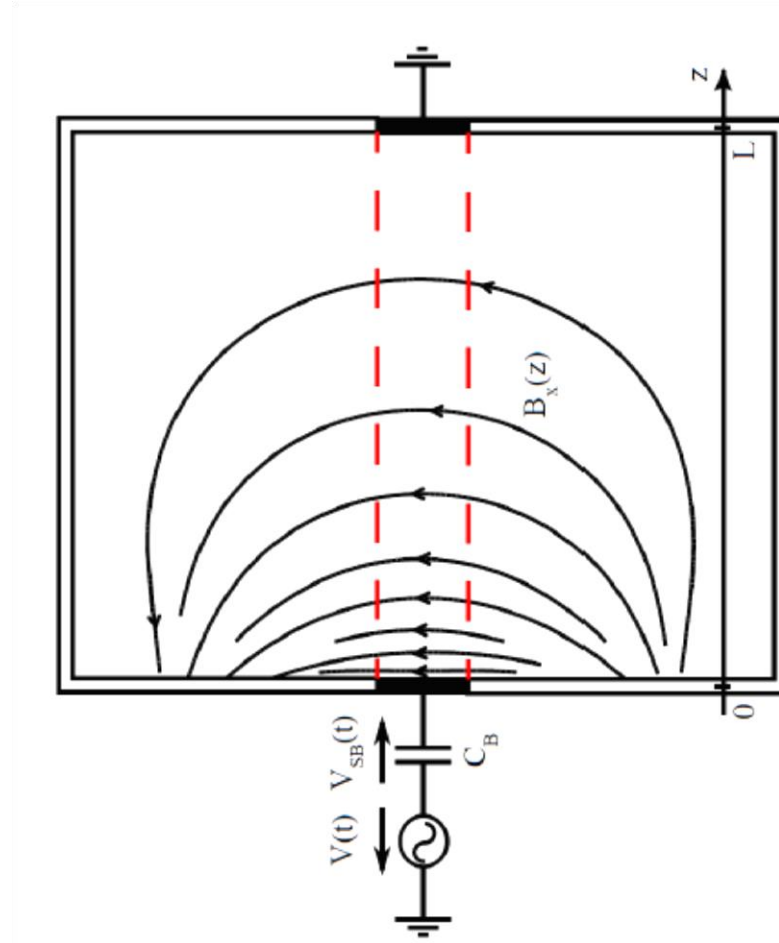
The code may predict an experiment





EST as postprocessing tool

- Simulation set up.

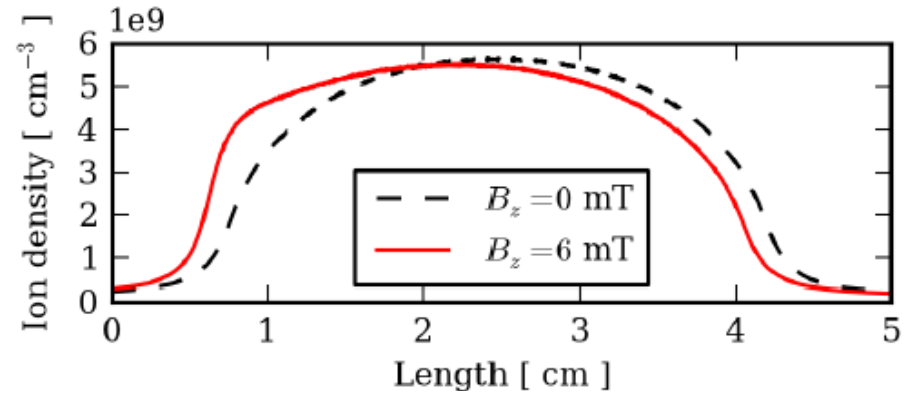


J. Trieschmann, M. Shihab et al J. Phys. D: Appl. Phys. **46** 084016 2013

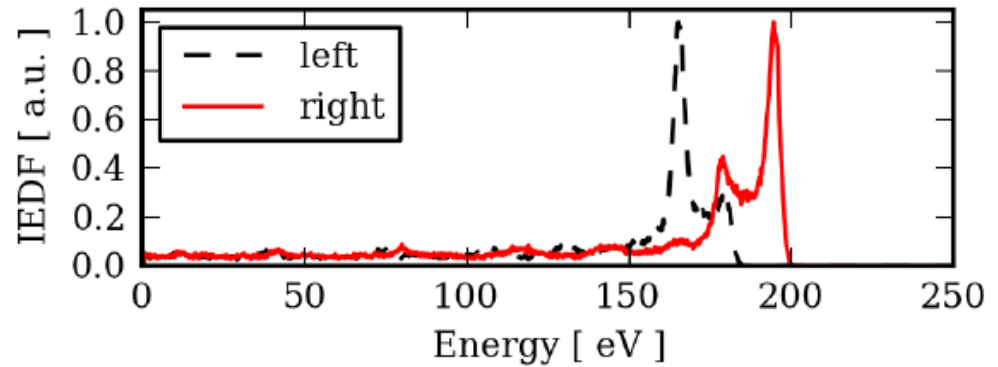


PIC results

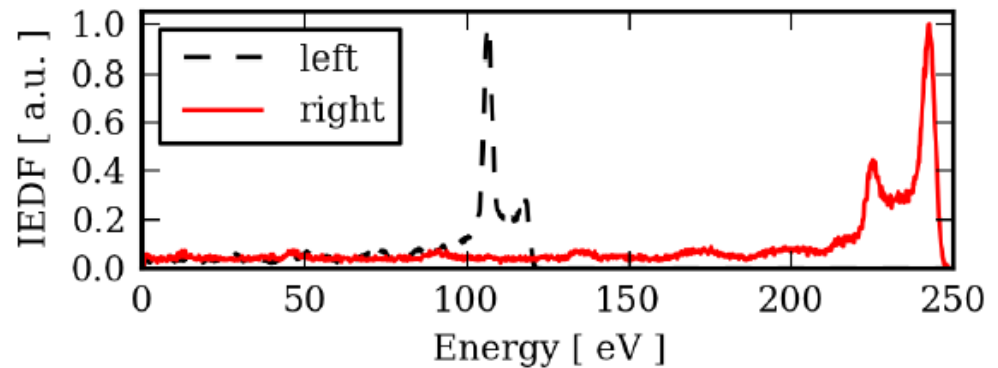
Ion density profile



IED- without B field



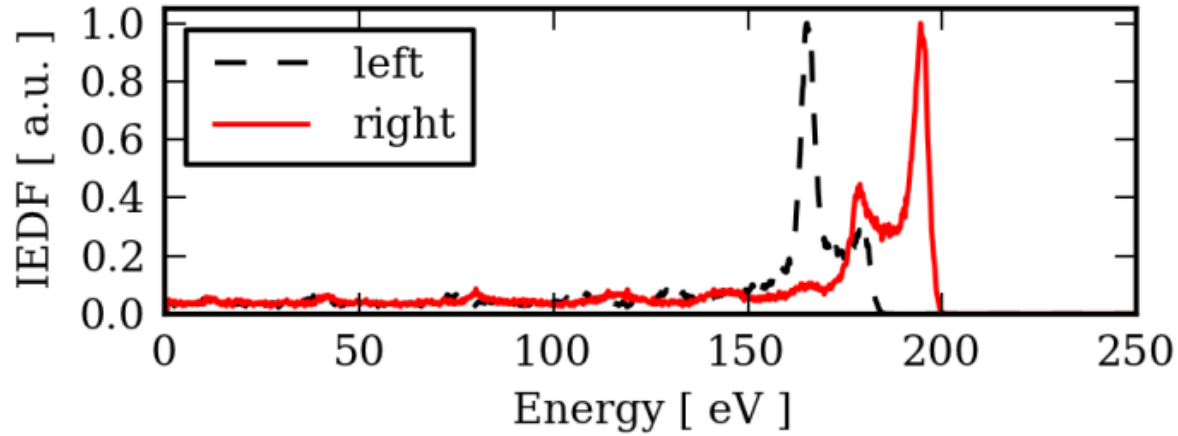
IED- with B field



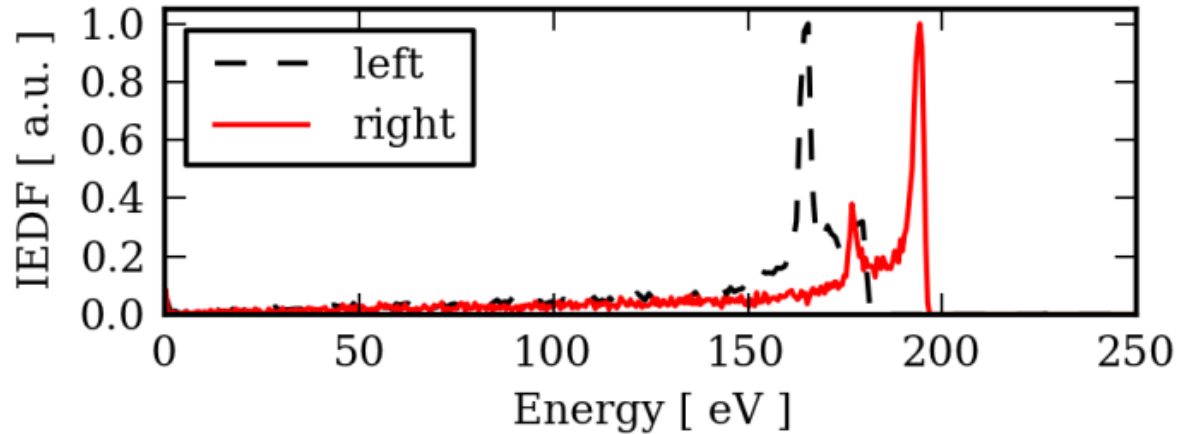


EST vs PIC

PIC



EST



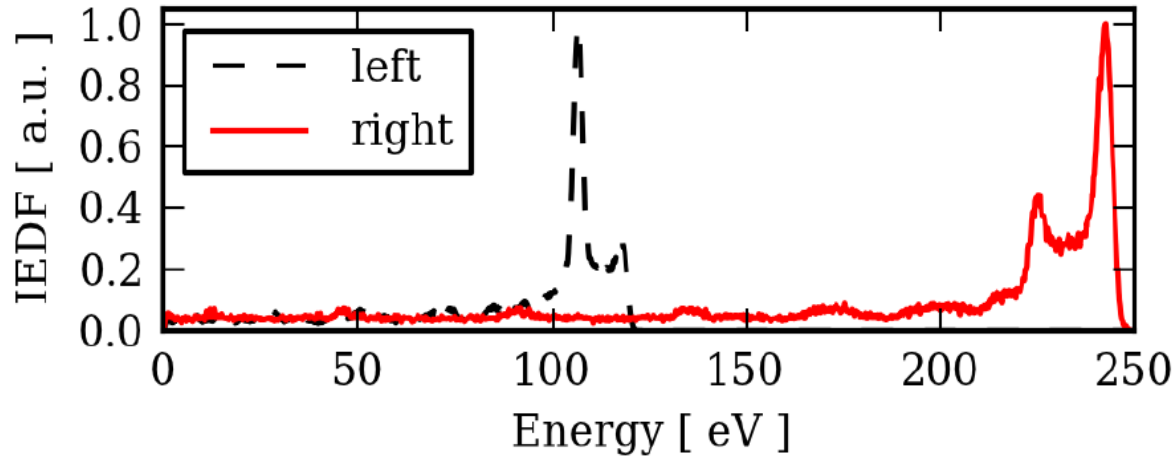
J. Trieschmann, M. Shihab et al J. Phys. D: Appl. Phys. **46** 084016 2013



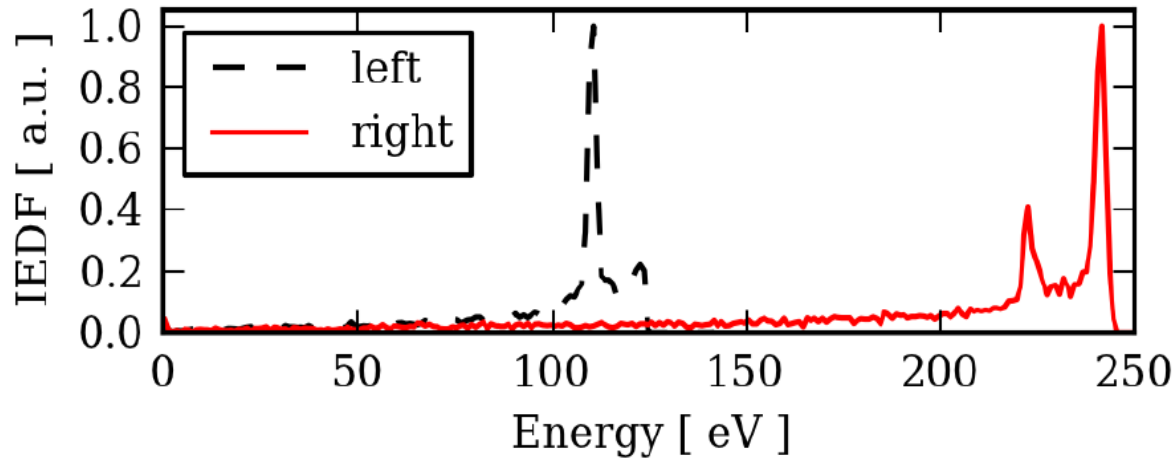


EST vs PIC

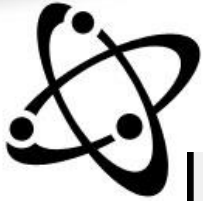
PIC



EST



J. Trieschmann, M. Shihab et al J. Phys. D: Appl. Phys. **46** 084016 2013



Experimental verification

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Experimental investigations of the magnetic asymmetry effect in capacitively coupled radio frequency plasmas

M Oberberg¹, J Källåhn¹, P Awakowicz¹ and J Schulze^{1,2}

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DOI 10.1088/1361-6595/aae199

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+ Article information

Abstract

The electrical asymmetry effect allows control of the discharge symmetry, the DC self-bias, and charged particle energy distribution functions electrically by driving a capacitive radio frequency

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Abstract

1. Introduction
2. Experimental set-up
3. Analytical RF sheath model
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The code may be a part in the experiment

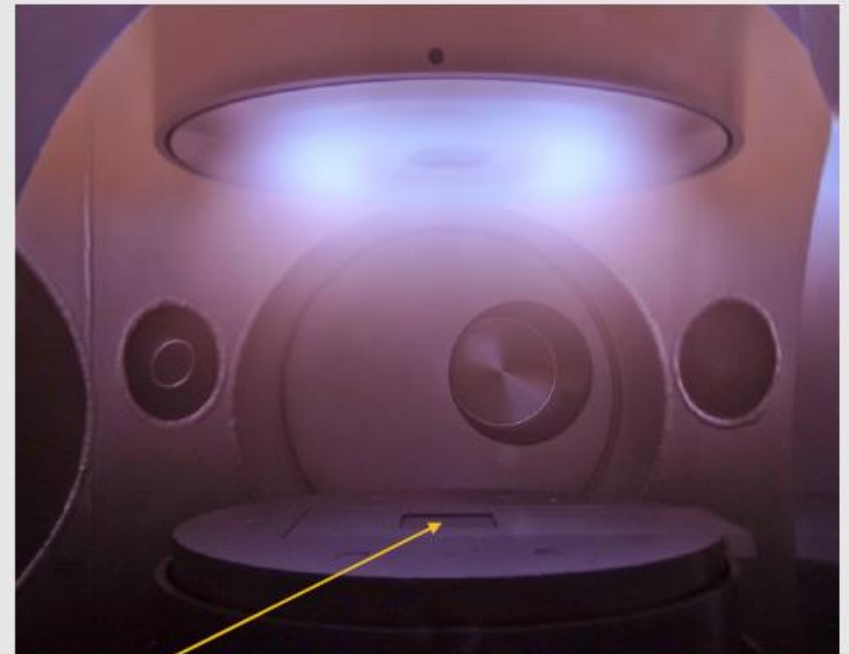




Deposition of Al_2O_3

The film stoichiometry is a function of the energy per deposited atom \bar{e} .

- Alumina is widely used:
 - microelectronics
 - hard coating
 - absorbent
 - catalyst
- Alumina is an insulator.
- IED can not be measured, then Simulation.



(Al + O₂ + Ar) on Si substrate

Prenzel, Ruhr University Bochum

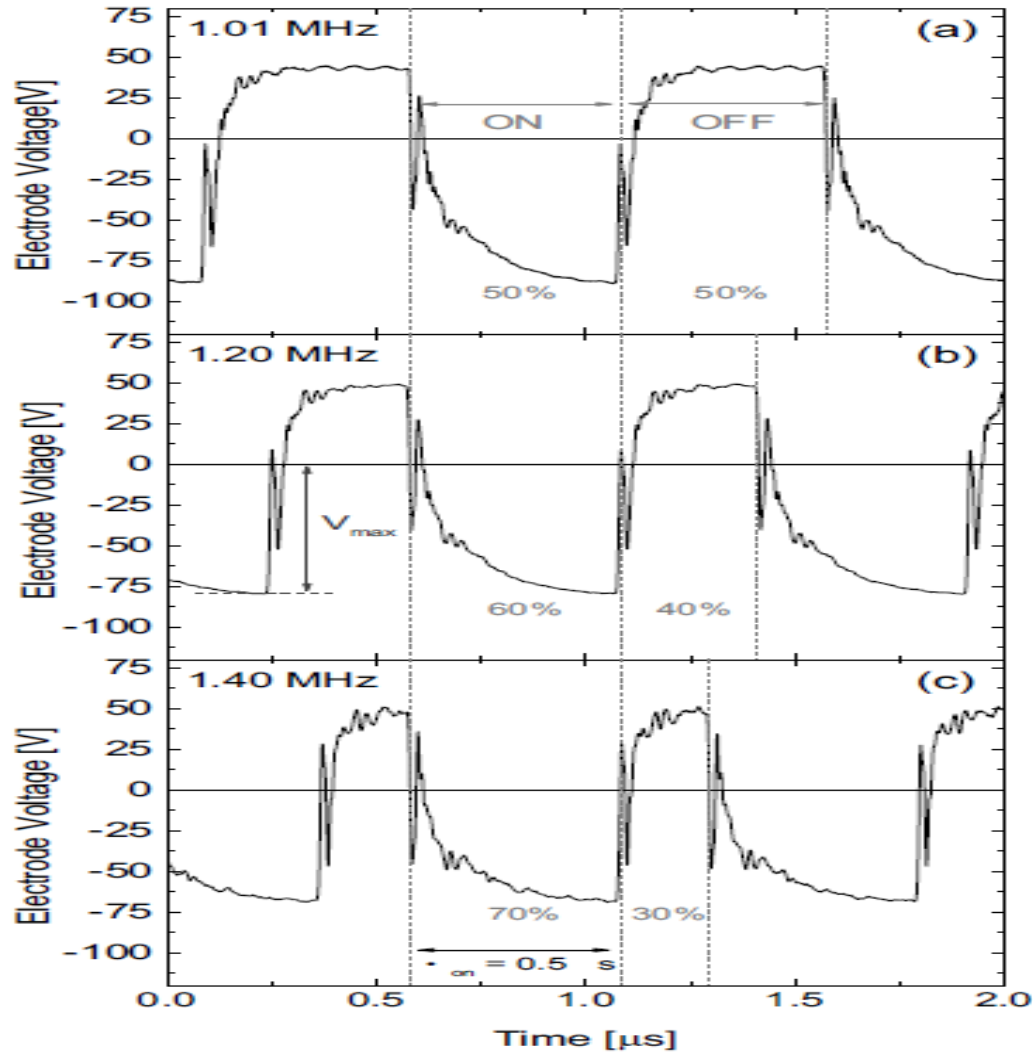
M. Prenzel , ... M. Shihab et al J. Phys. D: Appl. Phys. **46** (2013)

084004



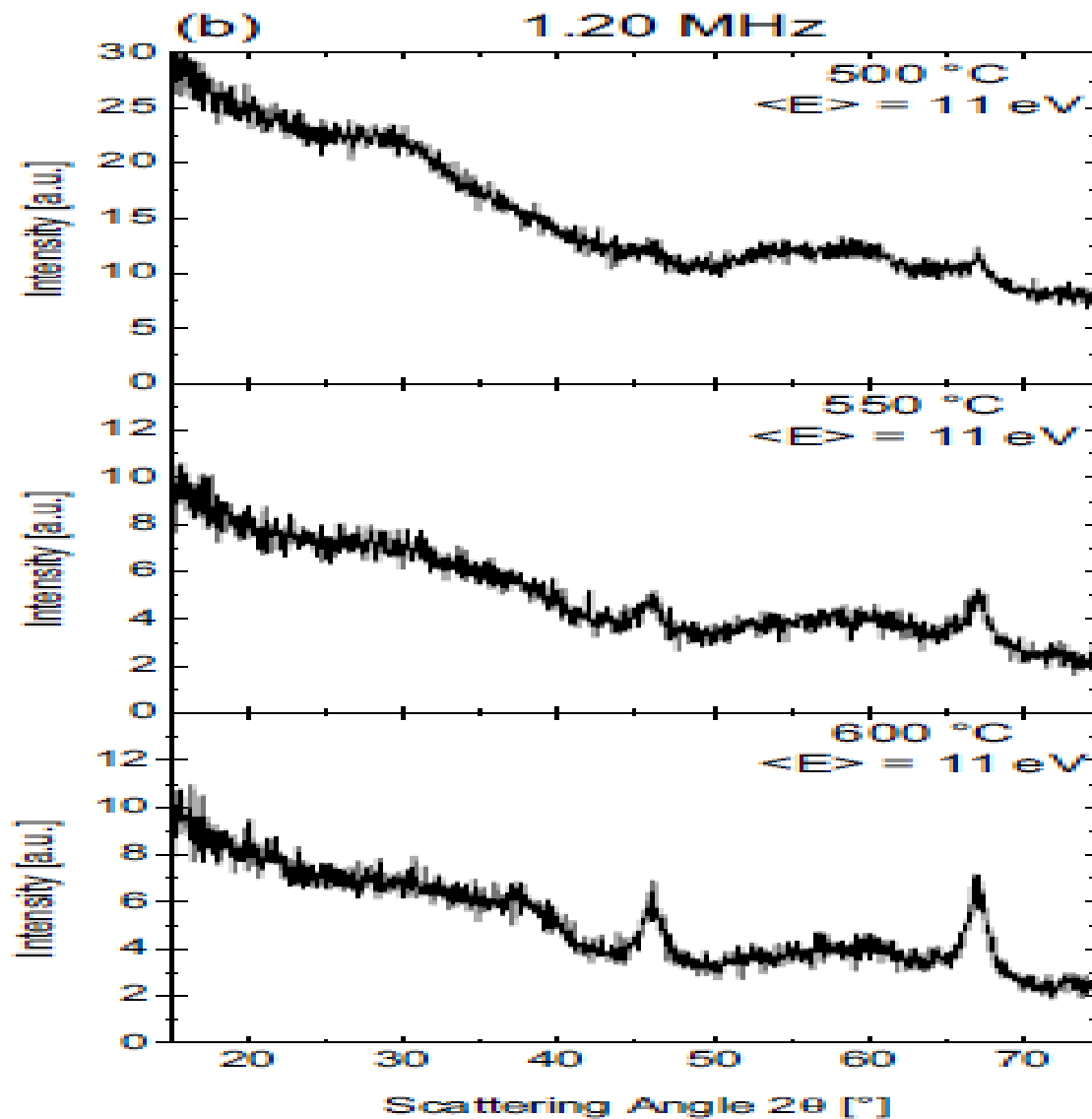


Aluminum Oxide Deposition I





Aluminum Oxide Deposition II





Conclusion

- The simulation gives approximate solution.
- There are different models: Kinetic models as PIC, Fluid models, global models, and hybrid models
- The results must be compared with analytical or experimental or simulated results.
- We should do calculations to interpret the experiment results, explain phenomena, or even propose an experiment.



Thanks!





Monte-Carlo Simulation

- Use random numbers to solve problems.
- Are numbers really random?

$$\frac{A_{sq}}{A_{sh}} = \frac{l^2}{\pi r^2}$$

$$\frac{A_{sq}}{A_{sh}} = \frac{4r^2}{\pi r^2} = \frac{N_{sq}}{N_{sp}}$$

$$\pi = 4 * N_{sp} / N_{sq}$$

